# 35A Digital MicroDLynxII<sup>™</sup>: Non-Isolated DC-DC Power Modules

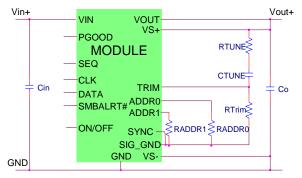
4.5Vdc -14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current



## **RoHS Compliant**

## Applications

- Distributed power architectures
- Intermediate bus voltage applications
- Telecommunications equipment
- Servers and storage applications
- Networking equipment
- Industrial equipment



# Features

- Compliant to RoHS II EU "Directive 2011/65/EU"
- Compatible in a Pb-free or SnPb reflow environment (Z versions)
- Compliant to IPC- 9592 (September 2008), Category 2, Class I
- Compliant to REACH Directive (EC) No 1907/2006
- DOSA based
- Wide Input voltage range (4.5Vdc-14.4Vdc)
- Output voltage programmable from 0.51Vdc to 3.63Vdc via external resistor and PMBus™#
- Digital interface through the PMBus<sup>™#</sup> protocol
- Tunable Loop<sup>™</sup> to optimize dynamic output voltage response
- Flexible output voltage sequencing EZ-SEQUENCE
- Power Good signal
- Fixed switching frequency with capability of external synchronization
- Output over current protection (non-latching)
- Over temperature protection
- Remote On/Off
- Ability to sink and source current
- Cost efficient open frame design
- Small size: 20.32 mm x 11.45 mm x 11 mm (0.8 in x 0.45 in x 0.433 in)
- Wide operating temperature range [-40°C to 85°C]
- UL\* 60950-1 2<sup>nd</sup> Ed. Recognized, CSA<sup>+</sup> C22.2 No. 60950-1-07 Certified, and VDE<sup>‡</sup> (EN60950-1 2<sup>nd</sup> Ed.) Licensed
- ISO\*\* 9001 and ISO 14001 certified manufacturing facilities

## Description

The 35A Digital MicroDLynxII<sup>TM</sup> power modules are non-isolated dc-dc converters that can deliver up to 35A of output current. These modules operate over a wide range of input voltage ( $V_{IN} = 4.5$ Vdc-14.4Vdc) and provide a precisely regulated output voltage from 0.51Vdc to 3.63Vdc, programmable via an external resistor and PMBus<sup>TM</sup> control. Features include a digital interface using the PMBus<sup>TM</sup> protocol, remote On/Off, adjustable output voltage, over current and over temperature protection. The PMBus<sup>TM</sup> interface supports a range of commands to both control and monitor the module. The module also includes the Tunable Loop<sup>TM</sup> feature that allows the user to optimize the dynamic response of the converter to match the load with reduced amount of output capacitance leading to savings on cost and PWB area.

\* UL is a registered trademark of Underwriters Laboratories, Inc.

<sup>†</sup> CSA is a registered trademark of Canadian Standards Association.

<sup>‡</sup> VDE is a trademark of Verband Deutscher Elektrotechniker e.V.
\*\* ISO is a registered trademark of the International Organization of Standards

# The PMBus name and logo are registered trademarks of the System Management Interface Forum (SMIF)



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## **Absolute Maximum Ratings**

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. These are absolute stress ratings only, functional operation of the device is not implied at these or any other conditions in excess of those given in the operations sections of the data sheet. Exposure to absolute maximum ratings for extended periods can adversely affect the device reliability.

Parameter	Device	Symbol	Min	Max	Unit
Input Voltage	All	V <sub>IN</sub>	-0.3	15	V
Continuous					
VS, ON/OFF, SEQ	All			7	V
CLK, DATA, SMBALERT#,SYNC	All		-0.3	3.6	V
Operating Ambient Temperature	All	T <sub>A</sub>	-40	85	°C
(see Thermal Considerations section)					
Storage Temperature	All	T <sub>stg</sub>	-55	125	°C

## **Electrical Specifications**

Unless otherwise indicated, specifications apply over all operating input voltage, resistive load, and temperature conditions.

Parameter	Device	Symbol	Min	Тур	Max	Unit
Operating Input Voltage	All	V <sub>IN</sub>	4.5		14.4	Vdc
Maximum Input Current	All	I <sub>IN,max</sub>			33	Adc
(V <sub>IN</sub> =4.5V to 14V, I <sub>O</sub> =I <sub>O, max</sub> )						
Input No Load Current	V <sub>0,set</sub> = 0.6 Vdc	I <sub>IN,No load</sub>		43		mA
$(V_{IN} = 12Vdc, I_0 = 0, module enabled)$	V <sub>0,set</sub> = 3.63Vdc	I <sub>IN,No load</sub>		106		mA
Input Stand-by Current ( $V_{IN} = 12Vdc$ , module disabled)	All	I <sub>IN,stand-by</sub>		16		mA
Inrush Transient	All	l²t			1	A <sup>2</sup> s
Input Reflected Ripple Current, peak-to-peak (5Hz to 20MHz, 1µH source impedance; V <sub>IN</sub> =0 to 14V, I₀= I₀max ; See Test Configurations)	All			35		mAp-p
Input Ripple Rejection (120Hz)	All			-71		dB
Output Voltage Set-point accuracy over entire output range						
0 to 85°C, Vo=over entire range	All	VO, set	-0.5		+0.5	% VO, set
-40 to 85°C, Vo=over entire range	All	VO, set	-1		+1	% VO, set
Voltage Regulation <sup>1</sup>						
Line Regulation	(VIN=V <sub>IN, min</sub> to V <sub>IN, max</sub> )			3		mV
Load (IO=IO, min to IO, max) Regulation	All			5		mV

<sup>1</sup>Worst case Line and load regulation data, all temperatures, from design verification testing as per IPC9592.

## Electrical Specifications (continued)

GE

Parameter	Device	Symbo	Min	Тур	Max	Unit
Adjustment Range (selected by an external resistor) (Some output voltages may not be possible depending on the input voltage – see Feature Descriptions Section)	All	Vo	0.6		3.63	Vdc
PMBus Adjustable Output Voltage Range	All	V <sub>o</sub> ,adj	-15	0	+10	%V <sub>0,set</sub>
PMBus Output Voltage Adjustment Step Size	All			0.4		%V <sub>O,set</sub>
Remote Sense Range	All				0.5	Vdc
Output Ripple and Noise on nominal output $(V_{IN}=V_{IN,nom} \text{ and } I_0=I_{0,min} \text{ to } I_{0,max} \text{ Co} = 0.1 \mu \text{F} // 8x47 \mu \text{F}$ ceramic capacitors) Peak-to-Peak (5Hz to 20MHz bandwidth) DMC (FUL to 20MHz bandwidth)	All			17		mV <sub>pk-pk</sub>
RMS (5Hz to 20MHz bandwidth)	All			3.2		mV <sub>rms</sub>
External Capacitance² Without the Tunable Loop™						
ESR≥1mΩ	All	C <sub>O, max</sub>	8x47		16×47	μF
With the Tunable Loop™						
ESR≥0.15 mΩ	All	C <sub>O, max</sub>	8x47		7000	μF
ESR≥10 mΩ	All	C <sub>O, max</sub>	8x47		8500	μF
Output Current (in either sink or source mode)	All	lo	0		35²	Adc
Output Current Limit Inception (Hiccup Mode) (current limit does not operate in sink mode)	All	I <sub>O, lim</sub>		413		Adcmax
Output Short-Circuit Current	All	I <sub>O, s/c</sub>		18		Arms
(V₀≤250mV) ( Hiccup Mode )						
Efficiency	V <sub>O,set</sub> = 0.6Vdc	η		80.2%		%
V <sub>IN</sub> = 12Vdc, T <sub>A</sub> =25°C	V <sub>O, set</sub> = 1.2Vdc	η		87.8%		%
I_O=I_O, max , V_O= V_O,set	V <sub>O,set</sub> = 1.8Vdc	η		91.4%		%
	V <sub>O,set</sub> = 2.5Vdc	η		93.2%		%
	V <sub>O,set</sub> = 3.3Vdc	η		94.3%		%
Switching Frequency	All	f <sub>sw</sub>		500		kHz

<sup>2</sup> External capacitors may require using the new Tunable Loop<sup>™</sup> feature to ensure that the module is stable as well as getting the best transient response. See the Tunable Loop<sup>™</sup> section for details.

<sup>3</sup> For ambient temperatures lower that -20C the minimum OCP is 30A. Monotonic start-up is guaranteed for output current 30A and below.

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4.5Vdc –14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

## Electrical Specifications (continued)

Parameter	Device	Symbol	Min	Тур	Max	Unit
Frequency Synchronization	All					
Synchronization Frequency Range (2 x f <sub>switch</sub> )	All		950	1000	1050	kHz
High-Level Input Voltage	All	VIH	2			V
Low-Level Input Voltage	All	VIL			0.4	V
Minimum Pulse Width, SYNC	All	t <sub>sync</sub>	100			ns
Maximum SYNC rise time	All	t <sub>sync_sh</sub>			100	ns

## **General Specifications**

Parameter	Device	Min	Тур	Max	Unit
Calculated MTBF (I_0=0.8I_0, max, T_A=40°C) Telecordia Issue 2 Method 1 Case 3	All		66,823,110		Hours
Weight			7.3		g (oz.)

## **Feature Specifications**

Unless otherwise indicated, specifications apply overall operating input voltage, resistive load, and temperature conditions. See Feature Descriptions for additional information.

Parameter	Device	Symbol	Min	Тур	Max	Unit
On/Off Signal Interface						
(V_IN=V_IN, min to V_IN, max ; open collector or equivalent,						
Signal referenced to GND)						
Device code with suffix "4" – Positive Logic (See Ordering Information)						
Logic High (Module ON)						
Input High Current	All	Ін			17	uA
Input High Voltage	All	Vih	2.1		7	V
Logic Low (Module OFF)						
Input Low Current	All	١L			2	uA
Input Low Voltage	All	VIL	-0.2		0.8	V
Device Code with no suffix – Negative Logic (See Ordering Information)						
(On/OFF pin is open collector/drain logic input with						
external pull-up resistor; signal referenced to GND)						
Logic High (Module OFF)						
Input High Current	All	Ін			3	mA
Input High Voltage	All	Vih	2.1		7	Vdc
Logic Low (Module ON)						
Input low Current	All	lı.			500	μΑ
Input Low Voltage	All	VIL	0		0.8	Vdc

## Feature Specifications (cont.)

Parameter	Device	Symbol	Min	Тур	Max	Units
Turn-On Delay and Rise Times						
(V_IN=V_{IN, nom,} I_0=I_{0, max}, V_0 to within $\pm 1\%$ of steady state)						
Case 1: On/Off input is enabled and then input power is applied (delay from instant at which $V_{IN} = V_{IN, min}$ until $V_0 = 10\%$ of $V_0$ , set)	All	Tdelay		1.2		msec
Case 2: Input power is applied for at least one second and then the On/Off input is enabled (delay from instant at which Von/Off is enabled until $V_0 = 10\%$ of $V_{0, set}$ )	All	Tdelay		1.1		msec
Output voltage Rise time (time for $V_0$ to rise from 10% of Vo, set to 90% of Vo, set)	All	Trise		2.7		msec
$ \begin{array}{l} \text{Output voltage overshoot} (T_A = 25^{\circ}\text{C} \\ \text{V}_{\text{IN}} = \text{V}_{\text{IN},  \text{min}} \text{ to } \text{V}_{\text{IN},  \text{max}}, \text{I}_{O} = \text{I}_{O,  \text{min}} \text{ to } \text{I}_{O,  \text{max}} ) \\ \text{With or without maximum external capacitance} \end{array} $					3.0	% V <sub>O, set</sub>
Over Temperature Protection (See Thermal Considerations section)	All	T <sub>OT</sub>		122		°C
PMBus Over Temperature Warning Threshold *	All	Twarn		105		°C
Tracking Accuracy (Power-Up: 2V/ms)	All	Vseq –Vo			100	mV
(Power-Down: 2V/ms)	All	Vseq –Vo			200	mV
(V_{IN,min} to V_{IN,max};I_{O,min} to $I_{O,max}$ OV < VSEQ $<$ Vo)						
Input Undervoltage Lockout						
Turn-on Threshold	All			4.25		Vdc
Turn-off Threshold	All			4.05		Vdc
Hysteresis	All			0.2		Vdc
PMBus Adjustable Input Under Voltage Lockout Thresholds	All		4		14	Vdc
Resolution of Adjustable Input Under Voltage Threshold	All		250			mV
PGOOD (Power Good)						
Signal Interface Open Drain, V <sub>supply</sub> ≤ 5VDC						
Overvoltage threshold for PGOOD ON	All			108.33		%V <sub>O, set</sub>
Overvoltage threshold for PGOOD OFF	All			112.5		%V <sub>O, set</sub>
Undervoltage threshold for PGOOD ON	All			91.67		%V <sub>O, set</sub>
Undervoltage threshold for PGOOD OFF	All			87.5		%V <sub>O, set</sub>
Pulldown resistance of PGOOD pin	All			40	70	Ω
Sink current capability into PGOOD pin	All				5	mA

\* Over temperature Warning – Warning may not activate before alarm and unit may shutdown before warning

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4.5Vdc -14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

## **Digital Interface Specifications**

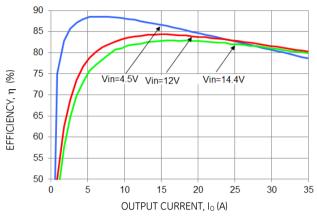
Unless otherwise indicated, specifications apply over all operating input voltage, resistive load, and temperature conditions. See Feature Descriptions for additional information.

Parameter	Conditions	Symbol	Min	Тур	Max	Unit			
PMBus Signal Interface Characteristics									
Input High Voltage (CLK, DATA)		Vih	2.1		3.6	V			
Input Low Voltage (CLK, DATA)		VIL			0.8	V			
Input high level current (CLK, DATA)		Ін	-10		10	μΑ			
Input low level current (CLK, DATA)		IIL	-10		10	μΑ			
Output Low Voltage (CLK, DATA, SMBALERT#)	Iout=2mA	Vol			0.4	V			
Output high level open drain leakage current (DATA, SMBALERT#)	V <sub>OUT</sub> =3.6V	I <sub>ОН</sub>	0		10	μΑ			
Pin capacitance		Co		0.7		pF			
PMBus Operating frequency range	Slave Mode	Fpmb	10		400	kHz			
Data hold time	Receive Mode Transmit Mode	thd:dat	0 300			ns			
Data setup time		tsu:dat	250			ns			
Measurement System Characteristics									
Output current measurement range		I <sub>RNG</sub>	0		50	А			
Output current measurement accuracy -40 to 85°C		I <sub>ACC</sub>	-7		5	%			
Temperature measurement accuracy @12Vin, 0°C to 85°C		T <sub>ACC</sub>		±10		°C			
V <sub>OUT</sub> measurement range		V <sub>OUT(rng)</sub>	0		4	V			
V <sub>OUT</sub> measurement accuracy		Vout, acc	-2		2	%			

### **Characteristic Curves**

GE

The following figures provide typical characteristics for the 35A Digital MicroDLyn×II™ at 0.6Vo and 25°C.



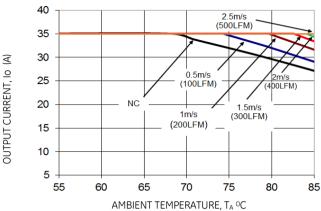
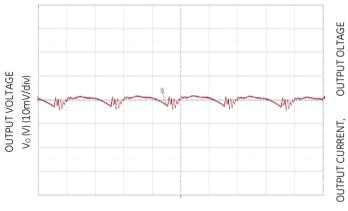


Figure 1. Converter Efficiency versus Output Current.



TIME, t (1µs/div)

Figure 2. Derating Output Current versus Ambient Temperature and Airflow.

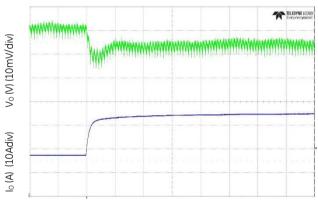


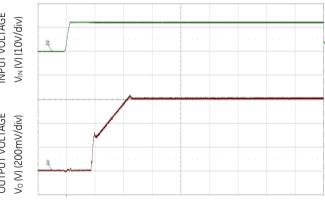
Figure 3. Typical output ripple ( $C_0=8x47\mu$ F ceramic,  $V_{IN}=12V$ ,  $I_0 = I_{0,max}$ ,).



TIME. t (2ms/div)

TIME, t (20µs /div)

Figure 4. Transient Response to Dynamic Load Change from 50% to 100% at 12Vin, Cout=8x47uF+24x330uF, CTune=18nF, RTune=300Ω



TIME. t (2ms/div)

Figure 6. Typical Start-up Using Input Voltage (VIN = 12V, Io = lo,max).

Figure 5. Typical Start-up Using On/Off Voltage (Io = Io,max).

1m/s (200LFM)

1.5m/s (300LFM)

2m/s 400LFM)

2.5m/s (500LFM)

## 35A Digital MicroDLynxII<sup>™</sup>: Non-Isolated DC-DC Power Modules 4.5Vdc -14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

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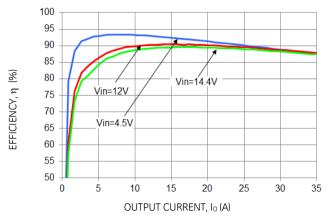
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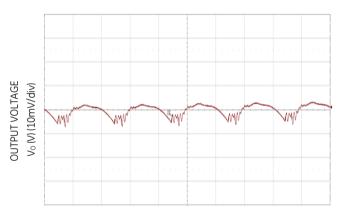
Z

## **Characteristic Curves**

The following figures provide typical characteristics for the 35A Digital MicroDLyn×II™ at 1.2Vo and 25°C.

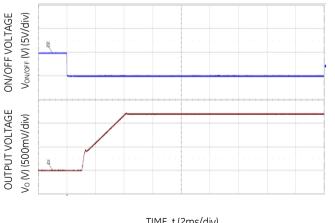




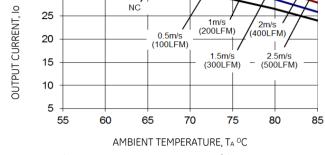


TIME, t (1µs/div)

Figure 9. Typical output ripple ( $C_0=8x47\mu$ F ceramic,  $V_{IN}=12V$ ,  $l_0 = l_{0,max}$ ).



TIME, t (2ms/div)



0.5m/s (100LFM)

NC

Figure 8. Derating Output Current versus Ambient Temperature and Airflow.

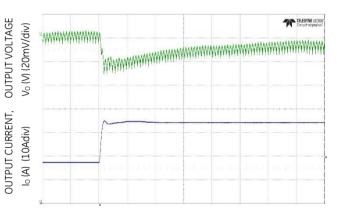
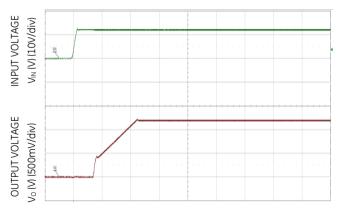


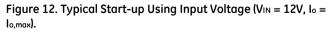


Figure 10. Transient Response to Dynamic Load Change from 50% to 100% at 12Vin, Cout=8x47uF+14x330uF, CTune=10nF, RTune=300Ω



TIME, t (2ms/div)

Figure 11. Typical Start-up Using On/Off Voltage (Io = Io,max).



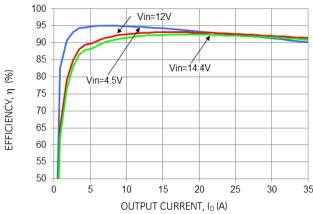
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4.5Vdc -14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

## **Characteristic Curves**

GE

The following figures provide typical characteristics for the 35A Digital MicroDLynxII<sup>™</sup> at 1.8Vo and 25°C.



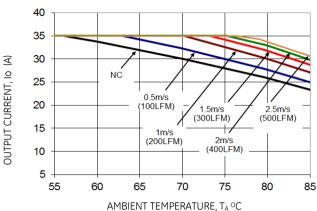
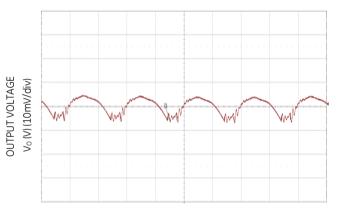


Figure 13. Converter Efficiency versus Output Current.



TIME, t (1µs/div)

Figure 14. Derating Output Current versus Ambient Temperature and Airflow.

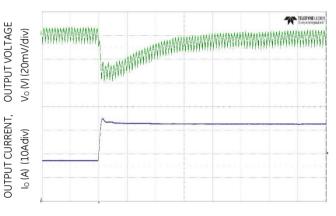
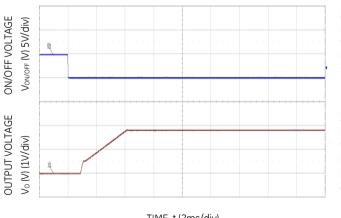


Figure 15. Typical output ripple and noise ( $C_0=8x47\mu$ F ceramic,  $V_{IN} = 12V$ ,  $I_0 = I_{0,max}$ , ).



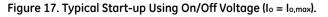
TIME, t (2ms/div)

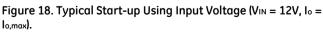
TIME, t (20µs /div)

Figure 16. Transient Response to Dynamic Load Change from 50% to 100% at 12Vin, Cout=8x47uF+7x330uF, CTune=4.7nF, RTune=221 $\Omega$ 



TIME, t (2ms/div)

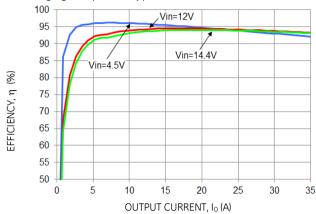


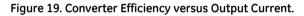


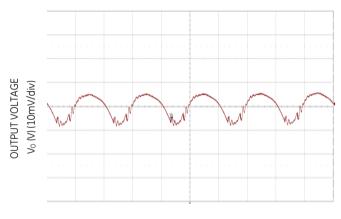
August 7, 2017

### **Characteristic Curves**

The following figures provide typical characteristics for the 35A Digital MicroDLynxII<sup>™</sup> at 2.5Vo and 25°C.

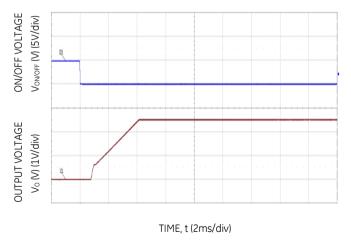


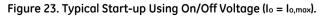




TIME, t (1µs/div)

Figure 21. Typical output ripple and noise (C\_0=8x47  $\mu$ F ceramic, V\_IN = 12V, I\_0 = I\_{0,max}, ).





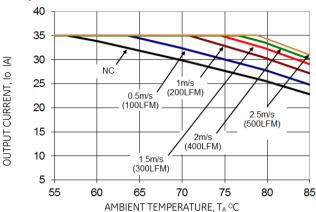


Figure 20. Derating Output Current versus Ambient Temperature and Airflow.

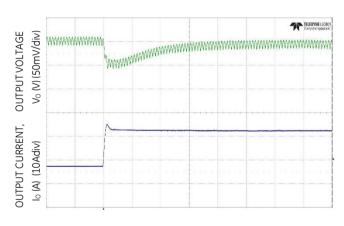
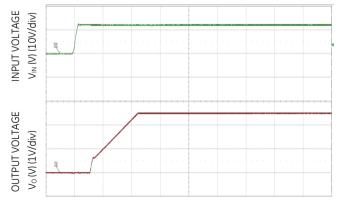




Figure 22. Transient Response to Dynamic Load Change from 50% to 100% at 12Vin, Cout=8x47uF+4x330uF, CTune=3300pF, RTune=221 $\Omega$ 



TIME, t (2ms/div)

Figure 24. Typical Start-up Using Input Voltage (ViN = 12V,  $I_{\rm O}$  =  $I_{\rm O,max}$ ).

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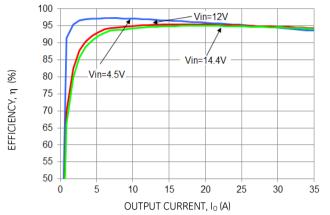
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OUTPUT CURRENT, IO

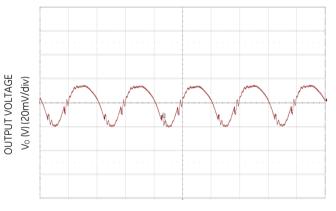
### **Characteristic Curves**

GE



The following figures provide typical characteristics for the 35A Digital MicroDLynxII<sup>™</sup> at 3.3Vo and 25°C.





TIME, t (1µs/div)

Figure 26. Derating Output Current versus Ambient Temperature and Airflow.

65

AMBIENT TEMPERATURE, TA °C

0.5m/s (100LFM)

> 1.0m/s (200LFM)

> > 70

1.5m/s (300LFM)

> 2.0m/s (400LFM)

> > 75

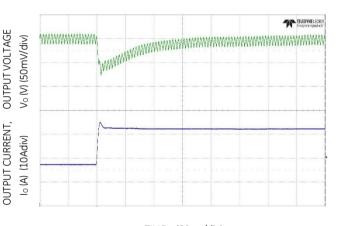
2.5m/s (500LFM)

80

85

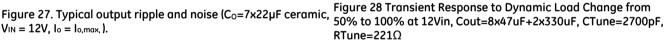
NC

60





TIME, t (20µs /div)

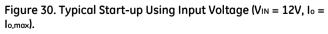




TIME, t (2ms/div)

TIME, t (2ms/div)

Figure 29. Typical Start-up Using On/Off Voltage ( $I_0 = I_{0,max}$ ).



ON/OFF VOLTAGE VowoFF (V) (5V/div)

OUTPUT VOLTAGE

Vo (V) (1V/div)

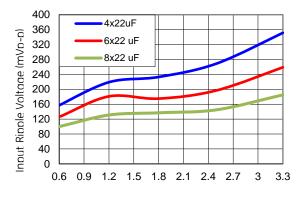
## **Design Considerations**

#### Input Filtering

GF

The 35A Digital MicroDLynxII<sup>™</sup> module should be connected to a low ac-impedance source. A highly inductive source can affect the stability of the module. An input capacitance must be placed directly adjacent to the input pin of the module, to minimize input ripple voltage and ensure module stability.

To minimize input voltage ripple, ceramic capacitors are recommended at the input of the module. Figure 31 shows the input ripple voltage for various output voltages at 35A of load current with  $4x22 \ \mu$ F,  $6x22 \ \mu$ F or  $8x22 \ \mu$ F ceramic capacitors and an input of 12V.



 $\label{eq:output Voltage (Vdc)} Figure 31. Input ripple voltage for various output voltages with 4x22 \ \mu\text{F}, 6x22 \ \mu\text{F} or 8x22 \ \mu\text{F} ceramic capacitors at the input (35A load). Input voltage is 12V. }$ 

#### **Output Filtering**

These modules are designed for low output ripple voltage and will meet the maximum output ripple specification with 0.1  $\mu$ F ceramic and 2x47  $\mu$ F ceramic capacitors at the output of the module. However, additional output filtering may be required by the system designer for a number of reasons. First, there may be a need to further reduce the output ripple and noise of the module. Second, the dynamic response characteristics may need to be customized to a particular load step change.

To reduce the output ripple and improve the dynamic response to a step load change, additional capacitance at the output can be used. Low ESR polymer and ceramic capacitors are recommended to improve the dynamic response of the module. Figure 32 provides output ripple information for different external capacitance values at various Vo and a full load current of 35A. For stable operation of the module, limit the capacitance to less than the maximum output capacitance as specified in the electrical specification table. Optimal performance of the module can be achieved by using the Tunable Loop<sup>™</sup> feature described later in this data sheet.

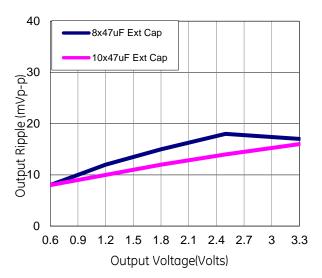


Figure 32. Output ripple voltage for various output voltages with external 4x47  $\mu$ F, 6x47  $\mu$ F or 8x47  $\mu$ F ceramic capacitors at the output (35A load). Input voltage is 12V.

## **Safety Considerations**

For safety agency approval the power module must be installed in compliance with the spacing and separation requirements of the end-use safety agency standards, i.e., ANSI/UL 60950-1 2<sup>nd</sup> Revised October 14, 2014, CSA C22.2 No. 60950-1-07, Second Ed. + A2:2014 (MOD), DIN EN 60950-1:2006 + A11:2009 + A1:2010 + A12:2011, + A2:2013 (VDE0805 Teil 1: 2014-08)(pending).

For the converter output to be considered meeting the requirements of safety extra-low voltage (SELV), the input must meet SELV requirements. The power module has extra-low voltage (ELV) outputs when all inputs are ELV. An external 40A 461 series Littelfuse fuse model or equivalent is recommended on the ungrounded input lead when the input voltage exceeds 8V. For input voltages less than 8V, 2 parallel 25A 456 series Littelfuse or equivalent are recommended on the ungrounded input lead.

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## **Analog Feature Descriptions**

#### Remote On/Off

The module can be turned ON and OFF either by using the ON/OFF pin (Analog interface) or through the PMBus interface (Digital). The module can be configured in a number of ways through the PMBus interface to react to the two ON/OFF inputs:

- Module ON/OFF can be controlled only through the analog interface (digital interface ON/OFF commands are ignored)
- Module ON/OFF can be controlled only through the PMBus interface (analog interface is ignored)
- Module ON/OFF can be controlled by either the analog or digital interface

The default state of the module (as shipped from the factory) is to be controlled by the analog interface only. If the digital interface is to be enabled, or the module is to be controlled only through the digital interface, this change must be made through the PMBus. These changes can be made and written to non-volatile memory on the module so that it is remembered for subsequent use.

#### Analog On/Off

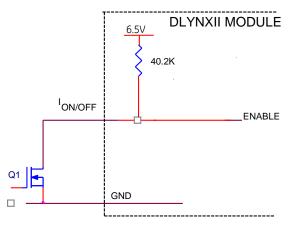
The 35A Digital MicroDLynxII<sup>™</sup> power modules feature an On/Off pin for remote On/Off operation. Two On/Off logic options are available. In the Positive Logic On/Off option, (device code suffix "4" – see Ordering Information), the module turns ON during a logic High on the On/Off pin and turns OFF during a logic Low. With the Negative Logic On/Off option, (no device code suffix, see Ordering Information), the module turns OFF during logic High and ON during logic Low. The On/Off signal should be always referenced to ground. For either On/Off logic option, leaving the On/Off pin disconnected will turn the module ON when input voltage is present.

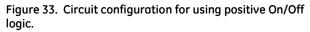
For positive logic modules, the circuit configuration for using the On/Off pin is shown in Figure 33. When the external transistor Q1 is in the OFF state, the internal PWM #Enable is pulled up internally, thus turning the module ON. When transistor Q1 is turned ON, the On/Off pin is pulled low, and consequently the internal PWM Enable signal is pulled low and the module is OFF.

For negative logic On/Off modules, the circuit configuration is shown in Fig. 34. The On/Off pin should be pulled high with an external pull-up resistor. When transistor Q2 is in the OFF state, the On/Off pin is pulled high, which pulls the internal ENABLE# High and the module is OFF. To turn the module ON, Q2 is turned ON pulling the On/Off pin low resulting in the PWM ENABLE# pin going Low. The maximum voltage allowed on the On/Off pin is 7V. If Vin is used as a source, then a suitable external resistor R1 must be used to ensure that the voltage on the On/Off pin does not exceed 7V

#### Digital On/Off

#### Please see the Digital Feature Descriptions section.





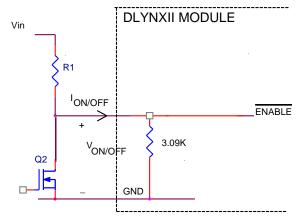


Figure 34. Circuit configuration for using negative On/Off logic.

#### Monotonic Start-up and Shutdown

The module has monotonic start-up and shutdown behavior for any combination of rated input voltage, output current and operating temperature range.

#### Startup into Pre-biased Output

The module can start into a prebiased output as long as the prebias voltage is 0.5V less than the set output voltage.

#### Analog Output Voltage Programming

The output voltage of the module is programmable to any voltage from 0.6dc to 3.63Vdc by connecting a resistor between the Trim and SIG\_GND pins of the module. Certain restrictions apply on the output voltage set point depending on the input voltage. These are shown in the Output Voltage vs. Input Voltage Set Point Area plot in Fig. 35. The Upper Limit curve shows that for output voltages lower than 1V, the input voltage must be lower than the maximum of 14.4V. The Lower Limit curve shows that for output voltages

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higher than 0.6V, the input voltage needs to be larger than the minimum of 4.5V. At output voltage of 2.5V, the input voltage should not be below 5Vin and at output voltage of 3.3V the input voltage should be at least 6Vin.

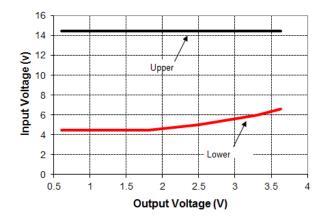
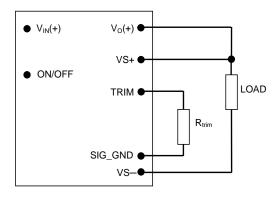


Figure 35. Output Voltage vs. Input Voltage Set Point Area plot showing limits where the output voltage can be set for different input voltages.



**Caution** – Do not connect SIG\_GND to GND elsewhere in the layout

Figure 36. Circuit configuration for programming output voltage using an external resistor.

Without an external resistor between Trim and SIG\_GND pins, the output of the module will be 0.6Vdc. To calculate the value of the trim resistor, *Rtrim* for a desired output voltage, should be as per the following equation:

$$Rtrim = \left[\frac{12}{(Vo - 0.6)}\right] k\Omega$$

Rtrim is the external resistor in  $k\Omega$ 

Vo is the desired output voltage.

Table 1 provides Rtrim values required for some common output voltages.

#### Table 1

V <sub>O, set</sub> (V)	Rtrim (KΩ)
0.6	Open
0.9	40
1.0	30
1.2	20
1.5	13.33
1.8	10
2.5	6.316
3.3	4.444

#### **Digital Output Voltage Adjustment**

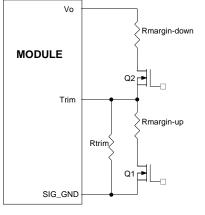
#### Please see the Digital Feature Descriptions section.

#### **Remote Sense**

The power module has a Remote Sense feature to minimize the effects of distribution losses by regulating the voltage between the sense pins (VS+ and VS-). The voltage drop between the sense pins and the VOUT and GND pins of the module should not exceed 0.5V.

#### Analog Voltage Margining

Output voltage margining can be implemented in the module by connecting a resistor, R<sub>margin-up</sub>, from the Trim pin to the ground pin for margining-up the output voltage and by connecting a resistor, R<sub>margin-down</sub>, from the Trim pin to output pin for margining-down. Figure 37 shows the circuit configuration for output voltage margining. The POL Programming Tool or Power Module Wizard(PMW), available at www.gecriticalpower.com under the Downloads section, also calculates the values of R<sub>margin-up</sub> and R<sub>margin-down</sub> for a specific output voltage and % margin. Please consult your local GE technical representative for additional details.



# Figure 37. Circuit Configuration for margining Output voltage.

#### Digital Output Voltage Margining

#### Please see the Digital Feature Descriptions section.

#### **Output Voltage Sequencing**

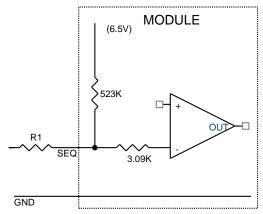
The power module includes a sequencing feature, EZ-SEQUENCE that enables users to implement various types of output voltage sequencing in their applications. This is accomplished via an additional sequencing pin. When not using the sequencing feature, leave it unconnected.

When an analog voltage is applied to the SEQ pin, the output voltage tracks this voltage until the output reaches the set-point voltage. The final value of the SEQ voltage must be set higher than the set-point voltage of the module. The output voltage follows the voltage on the SEQ pin on a one-to-one basis. By connecting multiple modules together, multiple modules can track their output voltages to the voltage applied on the SEQ pin.

For proper voltage sequencing, first, input voltage is applied to the module. The On/Off pin of the module is left unconnected (or tied to GND for negative logic modules or tied to V<sub>IN</sub> for positive logic modules) so that the module is ON by default. After applying input voltage to the module, a minimum 10msec delay is required before applying voltage on the SEQ pin. This delay gives the module enough time to complete its internal power-up soft-start cycle. During the delay time, the SEQ pin should be held close to ground (nominally 50mV  $\pm$  20 mV). This is required to keep the internal op-amp out of saturation thus preventing output overshoot during the start of the sequencing ramp. By selecting resistor R1 (see fig. 38) according to the following equation

$$R1 = \frac{26150}{6.5 - 0.05} = 4052 \text{ ohms, } (4.02 \text{K Std.})$$

the voltage at the sequencing pin will be 50mV when the sequencing signal is at zero.



# Figure 38. Circuit showing connection of the sequencing signal to the SEQ pin.

After the 10msec delay, an analog voltage is applied to the SEQ pin and the output voltage of the module will track this voltage on a one-to-one volt bases until the output reaches the set-point voltage. To initiate simultaneous shutdown of the modules, the SEQ pin voltage is lowered in a controlled manner. The output voltage of the modules tracks the voltages below their set-point voltages on a one-to-one basis. A valid input voltage must be maintained until the tracking and output voltages reach ground potential.

When using the EZ-SEQUENCE<sup>™</sup> feature to control start-up of the module, pre-bias immunity during start-up is disabled. The pre-bias immunity feature of the module relies on the module being in the diode-mode during start-up. When using the EZ-SEQUENCE<sup>™</sup> feature, modules goes through an internal set-up time of 10msec, and will be in synchronous rectification mode when the voltage at the SEO pin is applied. This will result in the module sinking current if a pre-bias voltage is present at the output of the module. When prebias immunity during start-up is required, the EZ-SEQUENCE<sup>™</sup> feature must be disabled. For additional guidelines on using the EZ-SEQUENCE<sup>™</sup> feature please refer to Application Note AN04-008 "Application Guidelines for Non-Isolated Converters: Guidelines for Sequencing of Multiple Modules", or contact the GE technical representative for additional information.

#### **Overcurrent Protection**

To provide protection in a fault (output overload) condition, the unit is equipped with internal current-limiting circuitry and can endure current limiting continuously. At the point of current-limit inception, the unit enters hiccup mode. The unit operates normally once the output current is brought back into its specified range.

#### Digital Adjustable Overcurrent Warning

#### Please see the Digital Feature Descriptions section.

#### **Overtemperature Protection**

To provide protection in a fault condition, the unit is equipped with a thermal shutdown circuit. The unit will shut down if the over-temperature threshold of 122 (typ) is exceeded at the thermal reference point  $T_{ref}$ . Please refer to Electrical characteristic table, over-temperature section on page 5. Once the unit goes into thermal shutdown it will then wait to cool before attempting to restart.

#### Digital Temperature Status via PMBus

Please see the Digital Feature Descriptions section.

# Digitally Adjustable Output Over and Under Voltage Protection

#### Please see the Digital Feature Descriptions section.

#### Input Undervoltage Lockout

At input voltages below the input undervoltage lockout limit, the module operation is disabled. The module will begin to operate at an input voltage above the undervoltage lockout turn-on threshold.

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Digitally Adjustable Input Undervoltage Lockout Please see the Digital Feature Descriptions section. Digitally Adjustable Power Good Thresholds

Please see the Digital Feature Descriptions section.

#### Synchronization

The module switching frequency can be synchronized to a signal with an external frequency within a specified range. Synchronization can be done by using the external signal applied to the SYNC pin of the module as shown in Fig. 39, with the converter being synchronized by the rising edge of the external signal. The Module switches at half the SYNC frequency. The Electrical Specifications table specifies the requirements of the external SYNC signal. If the SYNC pin is not used, the module will free run at the default switching frequency. **If synchronization is not being used, connect the SYNC pin to SIG\_GND**.

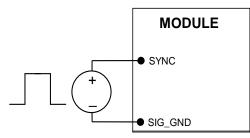


Figure 39. External source connections to synchronize switching frequency of the module.

# Measuring Output Current, Output Voltage and Temperature

#### Please see the Digital Feature Descriptions section.

#### **Dual Layout**

Identical dimensions and pin layout of Analog and Digital MicroDLynxII modules permit migration from one to the other without needing to change the layout. In both cases the trim resistor is connected between trim and signal ground. The output of the analog module cannot be trimmed down to 0.51V

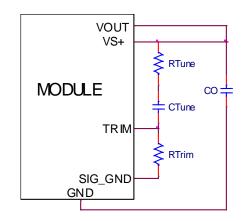
#### Tunable Loop™

The module has a feature that optimizes transient response of the module called Tunable  $Loop^{TM}$ .

External capacitors are usually added to the output of the module for two reasons: to reduce output ripple and noise (see Figure 38) and to reduce output voltage deviations from the steady-state value in the presence of dynamic load current changes. Adding external capacitance however affects the voltage control loop of the module, typically causing the loop to slow down with sluggish response. Larger values of external capacitance could also cause the module to become unstable.

The Tunable  ${\rm Loop}^{\rm TM}$  allows the user to externally adjust the voltage control loop to match the filter network connected to

the output of the module. The Tunable  $Loop^{TM}$  is implemented by connecting a series R-C between the VS+ and TRIM pins of the module, as shown in Fig. 40. This R-C allows the user to externally adjust the voltage loop feedback compensation of the module.



# Figure. 40. Circuit diagram showing connection of $R_{\text{TUME}}$ and $C_{\text{TUNE}}$ to tune the control loop of the module.

Recommended values of  $R_{TUNE}$  and  $C_{TUNE}$  for different output capacitor combinations are given in Tables 2 and 3. Table 3 shows the recommended values of  $R_{TUNE}$  and  $C_{TUNE}$  for different values of ceramic output capacitors up to 1000uF that might be needed for an application to meet output ripple and noise requirements. Selecting  $R_{TUNE}$  and  $C_{TUNE}$ according to Table 3 will ensure stable operation of the module.

In applications with tight output voltage limits in the presence of dynamic current loading, additional output capacitance will be required. Table 3 lists recommended values of  $R_{TUNE}$  and  $C_{TUNE}$  in order to meet 2% output voltage deviation limits for some common output voltages in the presence of a 10A to 35A step change (50% of full load), with an input voltage of 12V.

Please contact your GE technical representative to obtain more details of this feature as well as for guidelines on how to select the right value of external R-C to tune the module for best transient performance and stable operation for other output capacitance values.

Table 2. General recommended values of of RTUNE and
C <sub>TUNE</sub> for Vin=12V and various external ceramic capacitor
combinations.

Со	16x47µF	20x47µF	24x47µF	30x47μF	40x47μF
RTUNE	300	300	300	300	300
CTUNE	470pF	560pF	680pF	820pF	1.2nF

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Table 3. Recommended values of  $R_{\text{TUNE}}$  and  $C_{\text{TUNE}}$  to obtain transient deviation of 2% of Vout for a 10A step load with Vin=12V.

Vo	3.3V	2.5V	1.8V	1.2V	0.6V
Co	8x47uF + 2x330uF	8x47uF + 4x330uF	8x47uF + 7x330uF	8x47uF + 14x330uF	8x47uF + 24x330uF
RTUNE	221Ω	221Ω	221Ω	300Ω	300Ω
CTUNE	2700pF	3300pF	4700pF	10nF	18nF
ΔV	50mV	43mV	32mV	18mV	12mV

Note: The capacitors used in the Tunable Loop tables are 47  $\mu$  F/3 m $\Omega$  ESR ceramic and 330  $\mu$  F/12 m $\Omega$  ESR polymer capacitors.

#### Power Module Wizard

GE offers a free web based easy to use tool that helps users simulate the Tunable Loop performance of the UJT035. Go to <u>http://ge.transim.com/pmd/Home</u> and sign up for a free account and use the module selector tool. The tool also offers downloadable Simplis/Simetrix models that can be used to assess transient performance, module stability, etc.

## **Digital Feature Descriptions**

#### **PMBus Interface Capability**

GF

The 35A Digital MicroDLynxII<sup>™</sup> power modules have a PMBus interface that supports both communication and control. The PMBus Power Management Protocol Specification can be obtained from <u>www.pmbus.org</u>. The modules support a subset of version 1.1 of the specification (see Table 6 for a list of the specific commands supported). Most module parameters can be programmed using PMBus and stored as defaults for later use.

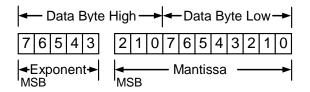
All communication over the module PMBus interface must support the Packet Error Checking (PEC) scheme. The PMBus master must generate the correct PEC byte for all transactions, and check the PEC byte returned by the module.

The module also supports the SMBALERT# response protocol whereby the module can alert the bus master if it wants to talk. For more information on the SMBus alert response protocol, see the System Management Bus (SMBus) specification.

The module has non-volatile memory that is used to store configuration settings. Not all settings programmed into the device are automatically saved into this non-volatile memory, only those specifically identified as capable of being stored can be saved (see Table 6 for which command parameters can be saved to non-volatile storage).

#### **PMBus Data Format**

For commands that set thresholds, voltages or report such quantities, the module supports the "Linear" data format among the three data formats supported by PMBus. The Linear Data Format is a two byte value with an 11-bit, two's complement mantissa and a 5-bit, two's complement exponent. The format of the two data bytes is shown below:



The value is of the number is then given by

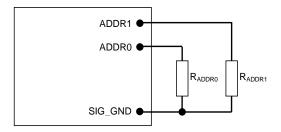
Value = Mantissa x 2 <sup>Exponent</sup>

#### PMBus Addressing

The power module can be addressed through the PMBus using a device address. The module has 64 possible addresses (0 to 63 in decimal) which can be set using resistors connected from the ADDR0 and ADDR1 pins to GND. Note that some of these addresses (0, 1, 2, 3, 4, 5, 6, 7, 8, 9, 10, 11 12, 40, 44, 45, 55 in decimal) are reserved according to the SMBus specifications and may not be useable. The address is set in the form of two octal (0 to 7) digits, with each pin setting one digit. The ADDR1 pin sets the high order digit and ADDR0 sets the low order digit. The resistor values suggested for each digit are shown in Table 4 (1% tolerance resistors are recommended). Note that if either address resistor value is outside the range specified in Table 4, the module will respond to address 127.

Tuble 4			
Digit	Resistor Value (KΩ)		
0	11		
1	18.7		
2	27.4		
3	38.3		
4	53.6		
5	82.5		
6	127		
7	187		

The user must know which I<sup>2</sup>C addresses are reserved in a system for special functions and set the address of the module to avoid interfering with other system operations. Both 100kHz and 400kHz bus speeds are supported by the module. Connection for the PMBus interface should follow the High Power DC specifications given in section 3.1.3 in the SMBus specification V2.0 for the 400kHz bus speed or the Low Power DC specifications in section 3.1.2. The complete SMBus specification is available from the SMBus web site, <u>smbus.org</u>.



# Figure 41. Circuit showing connection of resistors used to set the PMBus address of the module.

#### **Operation (01h)**

This is a paged register. The OPERATION command can be use to turn the module on or off in conjunction with the ON/OFF pin input. It is also used to margin up or margin down the output voltage

#### PMBus Enabled On/Off

The module can also be turned on and off via the PMBus interface. The OPERATION command is used to actually turn the module on and off via the PMBus, while the ON\_OFF\_CONFIG command configures the combination of analog ON/OFF pin input and PMBus commands needed to turn the module on and off. Bit [7] in the OPERATION command data byte enables the module, with the following functions:

- 0 : Output is disabled
- 1 : Output is enabled

This module uses the lower five bits of the ON\_OFF\_CONFIG data byte to set various ON/OFF options as follows:

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Bit Position	4	3	2	1	0
Access	r/w	r/w	r/w	r/w	r
Function	PU	CMD	CPR	POL	CPA
Default Value	1	0	1	1	0

PU: Sets the default to either operate any time input power is present or for the ON/OFF to be controlled by the analog ON/OFF input and the PMBus OPERATION command. This bit is used together with the CP, CMD and ON bits to determine startup.

Bit Value	Action
0	Module powers up any time power is present regardless of state of the analog ON/OFF pin
1	Module does not power up until commanded by the analog ON/OFF pin and the OPERATION command as programmed in bits [2:0] of the ON_OFF_CONFIG register.

CMD: The CMD bit controls how the device responds to the OPERATION command.

Bit Value	Action
0	Module ignores the ON bit in the OPERATION command
1	Module responds to the ON bit in the OPERATION command

CPR: Sets the response of the analog ON/OFF pin. This bit is used together with the CMD, PU and ON bits to determine startup.

Bit Value	Action
0	Module ignores the analog ON/OFF pin, i.e. ON/OFF is only controlled through the PMBUS via the OPERATION command
1	Module requires the analog ON/OFF pin to be asserted to start the unit

CPA: Sets the action of the analog ON/OFF pin when turning the controller OFF. This bit is internally read and cannot be modified by the user

#### PMBus Adjustable Soft Start Rise Time

The soft start rise time can be adjusted in the module via PMBus. When setting this parameter, make sure that the charging current for output capacitors can be delivered by the module in addition to any load current to avoid nuisance tripping of the overcurrent protection circuitry during startup. The TON\_RISE command sets the rise time in ms, and allows choosing soft start times between 600µs and 9ms, with possible values listed in Table 5. Note that the exponent is fixed at -4 (decimal) and the upper two bits of the mantissa are also fixed at 0.

#### Table 5

Rise Time	Exponent	Mantissa
600µs	11100	0000001010
900µs	11100	0000001110
1.2ms	11100	0000010011
1.8ms	11100	00000011101
2.7ms	11100	00000101011
4.2ms	11100	00001000011
6.0ms	11100	00001100000
9.0ms	11100	00010010000

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#### **Output Voltage Adjustment Using the PMBus**

The VREF\_TRIM parameter is important for a number of PMBus commands related to output voltage trimming, and margining. Each of the 2 output voltages of the module can be set as the combination of the voltage divider formed by RTrim and a  $20k\Omega$  upper divider resistor inside the module, and the internal reference voltage of the module. The reference voltage VREF is be nominally set at 600mV, and the output regulation voltage is then given by:

$$V_{OUT} = \left[\frac{20000 + RTrim}{RTrim}\right] \times V_{REF}$$

Hence the module output voltage is dependent on the value of RTrim which is connected external to the module.

The VREF TRIM parameter is used to apply a fixed offset voltage to the reference voltage can be specified using the "Linear" format and two bytes. The exponent is fixed at -9 (decimal). The resolution of the adjustment is 7 bits, with a resulting step size of approximately 0.4%. The maximum trim range is -20% to +10% of the nominal reference voltage(600mV) in 2mV steps. Possible values range from -120mV to +60mV. The exception is at 0.6Vout where the allowable trim range is only -90mV to +60mV to prevent the module from operating at lower than 0.51Vdc. When trimming the voltage below 0.6V, the module max. input voltage operating point also reduces proportionally. As shown earlier in Fig.41, the maximum permissible input voltage is 13V. For any voltage trimmed below 0.6V, the maximum input voltage will have to be reduced by the same factor.

When PMBus commands are used to trim or margin the output voltage, the value of  $V_{\text{REF}}$  is what is changed inside the module, which in turn changes the regulated output voltage of the module.

The nominal output voltage of the module is adjustable with a minimum step size of 0.4% over a +10% to -20% range from nominal using the VREF\_TRIM command over the PMBus.

The VREF\_TRIM command can be used to apply a fixed offset voltage to either of the output voltage command value using the "Linear" mode with the exponent fixed at -9 (decimal). The value of the offset voltage is given by

$$V_{REF(offset)} = VREF \_TRIM \times 2^{-9}$$

This offset voltage is added to the voltage set through the divider ratio and nominal  $V_{REF}$  to produce the trimmed output voltage. If a value outside of the +10%/-20% adjustment range is given with this command, the module will set it's output voltage to the upper or lower limit value (as if VOUT\_TRIM, assert SMBALRT#, set the CML bit in STATUS\_BYTE and the invalid data bit in STATUS\_CML.

#### **Applications Example**

For a design where the output voltage is 1.8V and the output needs to be trimmed down by 20mV.

• The internal reference voltage is 0.6V. So we need to determine how the 20mV translates to a change in the internal reference voltage.

- Divider Ratio = Vref/Vout = 0.6/1.8 = 0.33
- Hence a 20mV change at 1.8Vo requires a 0.33x20mV = 6.6mV change in the reference voltage.
- Vref(offset) = (6.6)/1000 = 0.0066 Volts (- sign since we are trimming down)
- V<sub>ref(offset)</sub> = V<sub>ref\_Trim</sub> x 2 <sup>-9</sup>
- Vref\_Trim = Vref(offset) x 512
- V<sub>ref\_Trim</sub> = -0.0066 × 512 = -3.3 = -3 (rounded to nearest integer

#### **Output Voltage Margining Using the PMBus**

The module can also have its output margined via PMBus commands. The command STEP\_VREF\_MARGIN\_HIGH will set the margin high voltage, while the command STEP\_VREF\_MARGIN\_LOW sets the margin low voltage. Both the STEP\_VREF\_MARGIN\_LOW commands will use the "Linear" mode with the exponent fixed at -9 (decimal). Two bytes are used for the mantissa with the upper bit [7] of the high byte fixed at 0. The actual margined output voltage is a combination of the STEP\_VREF\_MARGIN\_LOW and the VREF\_TRIM values as shown below. The net permissible voltage range change is - 30% to +10% for the margin high command and -20% to 0% for the margin low command

#### $V_{REF\,(MH)} =$

#### $(STEP\_VREF\_MARGIN\_HIGH+VREF\_TRIM) \times 2^{-9}$ Applications Example

For a design where the output voltage is 1.2V and the output needs to be trimmed up by 100mV (within 10% of Vo).
The internal reference voltage is 0.6V. So we need to determine how the 100mV translates to a change in the internal reference voltage.

- Divider Ratio = Vref/Vout = 0.6/1.2 = 0.5
- Hence a 100mV change at 1.2Vo requires a 0.5x100mV = 50mV change in the reference voltage.
- V<sub>REF(MH)</sub> = (50)/1000 = 0.05 Volts
- VREF(MH) = (Step\_Vref\_margin\_high + Vref\_trim) x 2 -9
- Assume V<sub>ref\_Trim</sub> = 0 here
- Step\_V<sub>ref\_margin\_high</sub> = V<sub>REF(MH)</sub> x 512
- Step\_V<sub>ref\_margin\_high</sub> = 0.05 x 25.6 = 26 (rounded to nearest integer

#### $V_{REF(ML)} =$

#### $(STEP \_VREF \_MARGIN \_LOW + VREF \_TRIM) \times 2^{-9}$ Applications Example

For a design where the output voltage is 1.8V and the output needs to be trimmed down by 100mV (within -20% of Vo). • The internal reference voltage is 0.6V. So we need to determine how the 100mV translates to a change in the internal reference voltage.

- Divider Ratio = Vref/Vout = 0.6/1.8 = 0.33
- Hence a 100mV change at 1.2Vo requires a 0.33×100mV = 33mV change in the reference voltage.
- $V_{\text{REF(MH)}} = -(33)/1000 = -0.033$  Volts (- sign since we are margining down)

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- VREF(ML) = (Step\_Vref\_margin\_low + Vref\_trim) x 2 -9
- Assume V<sub>ref\_Trim</sub> = 3 here (from V <sub>Ref\_Trim</sub> example earlier)
- Step\_Vref\_margin\_low = VREF(ML) x 512 Vref\_trim
- Step\_V<sub>ref\_margin\_low</sub> = -0.033 × 512 (-3) = -16.9+3 = -13.9 = -14 (rounded to nearest integer

The module will support the margined high or low voltages using the OPERATION command. Bits [5:2] are used to enable margining as follows:

•	00XX	:	Margin Off
•	0101		Margin Low (Act on

- 0101 : Margin Low (Act on Fault)
- O110 : Margin Low (Act on Fault)
- 1001 : Margin High (Act on Fault)
   1010 · Margin High (Act on Fault)
- 1010 : Margin High (Act on Fault)

#### PMBus Adjustable Overcurrent Warning

The module can provide an overcurrent warning via the PMBus. The threshold for the overcurrent warning can be set using the parameter IOUT\_OC\_WARN\_LIMIT. This command uses the "Linear" data format with a two byte data word where the upper five bits [7:3] of the high byte represent the exponent and the remaining three bits of the high byte [2:0] and the eight bits in the low byte represent the mantissa. The exponent is fixed at –1 (decimal). The upper five bits of the mantissa are fixed at 0 while the lower six bits are programmable with a default value of 19A (decimal). The resolution of this warning limit is 500mA. The value of the IOUT\_OC\_WARN\_LIMIT can be stored to non-volatile memory using the STORE\_DEFAULT\_ALL command

#### **Temperature Status via PMBus**

The module will provide information related to temperature of the module through the READ\_TEMPERATURE\_2 command. The command returns external temperature in degrees Celsius. This command will use the "Linear" data format with a two byte data word where the upper five bits [7:3] of the high byte will represent the exponent and the remaining three bits of the high byte [2:0] and the eight bits in the low byte will represent the mantissa. The exponent is fixed at 0 (decimal). The lower 11 bits are the result of the ADC conversion of the external temperature

# PMBus Adjustable Output Over, Under Voltage Protection and Power Good

The module has a common command to set the PGOOD, VOUT\_UNDER\_VOLTAGE(UV) and VOUT\_OVER\_VOLTAGE (OV) limits as a percentage of nominal. Refer to Table 6 of the next section for the available settings. The PMBus command VOUT\_OVER\_VOLTAGE (OV) is used to set the output over voltage threshold from two possible values: +12.5% or +16.67% of the commanded output voltage for each output.

The module provides a Power Good (PGOOD) that is implemented with an open-drain output to indicate that the output voltage is within the regulation limits of the power module. The PGOOD signal is de-asserted to a low state if any condition such as overtemperature, overcurrent or loss of regulation occurs that would result in the output voltage going outside the specified thresholds. The PGOOD thresholds are user selectable via the PMBus (the default values are as shown in the Feature Specifications Section). Each threshold is set up symmetrically above and below the nominal value. The PGL (POWERGOODLOW) command will set the output voltage level above which PGOOD is asserted (lower threshold). The PGH(POWERGOODHIGH) command will set the level above which the PGOOD command is deasserted. This command will also set two thresholds symmetrically placed around the nominal output voltage. Normally, the PGL threshold is set higher than the PGH threshold.

The PGOOD terminal can be connected through a pullup resistor (suggested value  $100 \text{K}\Omega$ ) to a source of 5VDC or lower. The current through the PGood terminal should be limited to a max value of 5mA

#### PMBus Adjustable Input Undervoltage Lockout

The module allows for adjustment of the input under voltage lockout and hysteresis. The command VIN\_ON allows setting the input voltage turn on threshold for each output, while the VIN\_OFF command will set the input voltage turn off threshold. For the VIN\_ON command, possible values are 4.25V to 16V in variable steps. For the VIN\_OFF command, possible values are 4V to 15.75V in 0.5V steps. If other values are entered for either command, they is mapped to the closest of the allowed values.

Both the VIN\_ON and VIN\_OFF commands use the "Linear" format with two data bytes. The upper five bits will represent the exponent (fixed at -2) and the remaining 11 bits will represent the mantissa. For the mantissa, the four most significant bits are fixed at 0.

#### Measurement of Output Current and Voltage

The module is capable of measuring key module parameters such as output current and voltage and providing this information through the PMBus interface.

#### Measuring Output Current Using the PMBus

The module measures current by using the inductor winding resistance as a current sense element. The inductor winding resistance is then the current gain factor used to scale the measured voltage into a current reading. This gain factor is the argument of the IOUT\_CAL\_GAIN command, and consists of two bytes in the linear data format. The exponent uses the upper five bits [7:3] of the high data byte in two-s complement format and is fixed at –4 (decimal). The remaining 11 bits in two's complement binary format represent the mantissa. During manufacture, each module is calibrated by measuring and storing the current gain factor into non-volatile storage. DONOT CHANGE THE FACTORY PROGRAMMED VALUE.

The current measurement accuracy is also improved by each module being calibrated during manufacture with the offset in the current reading. The IOUT\_CAL\_OFFSET command is used to store and read the current offset. The argument for this command consists of two bytes composed of a 5-bit exponent (fixed at -4d) and a 11-bit

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mantissa. This command has a resolution of 62.5mA and a range of  $\,$  -4000mA to +3937.5mA. DONOT CHANGE THE FACTORY PROGRAMMED VALUE.

The READ\_IOUT command provides module average output current information. This command only supports positive or current sourced from the module. If the converter is sinking current a reading of 0 is provided. The READ\_IOUT command returns two bytes of data in the linear data format. The resolution of the command is 62.5mA. The exponent uses the upper five bits [7:3] of the high data byte in two-s complement format and is fixed at –4 (decimal). The remaining 11 bits in two's complement binary format represent the mantissa with the 11<sup>th</sup> bit fixed at 0 since only positive numbers are considered valid.

#### Measuring Output Voltage Using the PMBus

The module provides output voltage information using the READ\_VOUT command for each output. In this module the output voltage is sensed at the remote sense amplifier output pin so voltage drop to the load is not accounted for. The command will return two bytes of data all representing the mantissa while the exponent is fixed at -9 (decimal).

#### Reading the Status of the Module using the PMBus

The module supports a number of status information commands implemented in PMBus. However, not all features are supported in these commands. A 1 in the bit position indicates the fault that is flagged.

STATUS\_BYTE : Returns one byte of information with a summary of the most critical device faults.

Bit Position	Flag	Default Value
7	Х	0
6	OFF	0
5	VOUT Overvoltage	0
4	IOUT Overcurrent	0
3	VIN Undervoltage	0
2	Temperature	0
1	CML (Comm. Memory Fault)	0
0	None of the above	0

STATUS\_WORD : Returns two bytes of information with a summary of the module's fault/warning conditions.

Bit Position	Flag	Default Value
7	Х	0
6	OFF	0
5	VOUT Overvoltage	0
4	IOUT Overcurrent	0
3	VIN Undervoltage	0
2	Temperature	0
1	CML (Comm. Memory Fault)	0
0	None of the above	0

**High Byte** 

Bit Position	Flag	Default Value
7	VOUT fault or warning	0
6	IOUT fault or warning	0
5	Х	0
4	MFR	0
3	POWER_GOOD# (is negated)	0
2	×	0
1	Х	0
0	X	0

STATUS\_VOUT : Returns one byte of information relating to the status of the module's output voltage related faults.

Bit Position	Flag	Default Value
7	VOUT OV Fault	0
6	X	0
5	Х	0
4	VOUT UV Fault	0
3	X	0
2	Х	0
1	X	0
0	X	0

STATUS\_IOUT : Returns one byte of information relating to the status of the module's output voltage related faults.

Bit Position	Flag	Default Value
7	IOUT OC Fault	0
6	Х	0
5	IOUT OC Warning	0
4	Х	0
3	Х	0
2	Х	0
1	X	0
0	X	0

STATUS\_TEMPERATURE : Returns one byte of information relating to the status of the module's temperature related faults.

Bit Position	Flag	Default Value
7	OT Fault	0
6	OT Warning	0
5	X	0
4	X	0
3	×	0
2	X	0
1	X	0
0	X	0

STATUS\_CML : Returns one byte of information relating to the status of the module's communication related faults.

Bit Position	Flag	Default Value
7	Invalid/Unsupported Command	0

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6	Invalid/Unsupported Command	0
5	Packet Error Check Failed	0
4	Memory Fault Detected	0
3	X	0
2	Х	0
1	Other Communication Fault	0
0	X	0

MFR\_VIN\_MIN : Returns minimum input voltage as two data bytes of information in Linear format (upper five bits are exponent – fixed at -2, and lower 11 bits are mantissa in two's complement format – fixed at 12)

MFR\_VOUT\_MIN : Returns minimum output voltage as two data bytes of information in Linear format (upper five bits are exponent – fixed at -10, and lower 11 bits are mantissa in two's complement format – fixed at 614)

MFR\_SPECIFIC\_00 : Returns information related to the type of module and revision number. Bits [7:2] in the Low Byte indicate the module type (010011 corresponds to the UJT035 series of module), while bits [7:3] indicate the revision number of the module.

	Low Byte	
Bit Position	Flag	Default Value
7:2	Module Name	010011
1:0	Reserved	10

**High Byte** 

Bit Position	Flag	Default Value
7:3	Module Revision Number	None
2:0	Reserved	000

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Summary of Supported PMBus Commands Please refer to the PMBus 1.1 specification for more details of these commands.

Table 6

Hex Code	Command			Bri	ief Desc	ription					Non-Volatile Memory Storage			
		Turn Module on or o	off. Also	used to	o margii	n the ou	itput vo	ltage						
		Format				Jnsigne	ed Binar	У						
		Bit Position	7	6	5	4	3	2	1	0				
		Access	r/w	r	r/w	r/w	r/w	r/w	r	r				
		Function	On	Х		1	rgin		Х	Х				
01	OPERATION	Default Value	0	0	0	0	0	0	Х	Х				
01		Bit 7:0 Output swit 1 Output s												
		Margin: 00XX Margi	in Off	y enub	ieu									
		0101 Marg	in Low (	Act on	fault)									
		0110 Marg	in Low (	Act on t	fault)									
		1001 Marg												
		1010 Marg Configures the ON/	IN HIGN	(Act on	tauit)	combin	ation of	analoo		Enin				
		and PMBus commo		ICLIONUI	ity as a	Compin		analog		грп				
		Format	1105			Jnsiane	ed Binar	V						
00		Bit Position	7	6	5	4	3	2	1	0				
02	ON_OFF_CONFIG	Access	r	r	r	r/w	r/w	r/w	r/w	r	YES			
		Function	Х	Х	Х	pu	cmd	cpr	pol	сра				
		Default Value	0	0	0	1	0	1	1	0				
		Refer to Page 19 fo												
03	CLEAR_FAULTS	Clear any fault bits				et, also i	releases	s the S№	1BALER	「# signal				
	_	if the device has be		0										
		Used to control writ												
		setting in the modu						e value	in the d	lata byte				
			to non-volatile memory (EEPROM) on the module Format Unsigned Binary											
		Bit Position	7	6	5	4	3	2	1	0				
		Access	r/w	r/w	r/w	X	×	X	X	×				
		Function	bit7	bit6	bit5	X	X	X	X	X				
		Default Value	0	0	0	Х	Х	Х	Х	Х				
10	WRITE_PROTECT	Bit5: 0 – Enables all									YES			
		1 – Disables all and ON_OF	writes	except i	the WRI	TE_PRO	TECT, P	AGE OP	ERATIO	N				
		Bit 6: 0 – Enables al												
		1 – Disables al						T. PAGE	Eand					
		OPERATION												
		Bit7: 0 – Enables all						_						
		1 – Disables all			for the V	VRITE_F	PROTEC	T comm	hand					
		(bit5 and bit	lo must	be 0)										
		Stores all of the aver	ront ot -	vabla -	naistar -	ottina-	in the r		mama	u ac the				
15	STORE_USER_ALL	Stores all of the cur new defaults on po		nuble re	egisters	eungs	in the E	EPKUM	memor	y us trie				
			wei up											
		Restores all of the s												
16	RESTORE_USER_ALL	(EEPROM). The com	mand s	hould n	ot be us	ed whil	e the de	evice is	actively					
		switching												
		This command help	os the h	ost syst	em/GUI	/CLI de	termine	key ca	oabilitie	s of the				
		module					10:							
		Format Bit Desition	7			· · · ·	ed Binar		1					
		Bit Position Access	7 r	6 r	5 r	4 r	3 r	2 r	1 r	0 r				
19	CAPABILITY	Function	r PEC		r PD	r ALRT	r	Rese	erved	r				
		Default Value	1	0	1	1	0	0	0	0				
		PEC – 1 Supported								· · · · ·				
		SPD -01 – max of 4												
		ALRT – 1 – SMBALE	RT# sup	ported										

Hex Code	Command			Br	ief Desc	ription					Non-Volatile Memory Storage
Coue		The module has MC	)DE set	to Line	ar and E	xponen	t set to	-10. Th	ese valu	Jes	Memory Storage
		cannot be changed				,	7		1		
		Bit Position Access	7 r	6 r	5 r	4 r	3 r	2 r	1 r	0 r	
20	VOUT_MODE	Function	I	Mode		I		Expone			
		Default Value	0	0	0	1	0	1	1	1	
		Mode: Value fixed a				<b>c</b> 1:			·		
		Exponent: Value fixe Sets the value of in	ed at 10	)111, Ex	ponent	tor line	ar mode	e values	s is -9		
		Format		<u> </u>	inear, tu				iry		
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r	r	r	r	r	r	r	
		Function Default Value	1		Exponer	nt 1	0	0	Mantiss 0	a 0	
		Bit Position	7	1 6	5	4	3	2	1	0	
		Access	r	r/w	r/w	r/w	r/w	r/w	r/w	r/w	
		Function				Man	tissa				
35	VIN_ON	Default Value	0	0	0	1	0	0	0	1	YES
		Exponent -2 (dec), f Mantissa	ixed								
		The upper four bits	are fixe	ed at 0							
		The lower seven are	e progra	ammab	le with o	a defaul	t value	of 9(de	c). This		
		corresponds to a de					es are				
		<ul> <li>4.25, in s</li> <li>9.5V to 1</li> </ul>									
		<ul> <li>9.5V to 1</li> <li>13V to 1</li> </ul>									
		- 157 (0 1			100 01 11						
		Sets the value of in Format	out volt						m /		
		Bit Position	7	6	inear, tv 5	vo s cor 4	npieme 3		1	0	
		Access	r	r	r	r	r	r	r	r	
		Function			Exponer	it			Mantiss	a	
		Default Value	1	1	1	1	0	0	0	0	
		Bit Position	7	6 r/w	5 r/w	4 r/w	3 r/w	2 r/w	1 r/w	0 r/w	
		Access Function	r	I/W	I/W		tissa	I/W	I/W	1700	
		Default Value	0	0	0	1	0	0	0	0	
7.6		Exponent -2 (dec), f	ixed								
36	VIN_OFF	Mantissa	c								YES
		The upper four bits The lower seven are			le with r	ı defaul	t value	of 81de	c) This		
		corresponds to a de			with t	. acruu	. value	5. 0,000	oj. 1110		
		Allowable values ar									
		• 4.00, in s					,				
		<ul> <li>10.25V t</li> <li>12V</li> </ul>	0 11.75	V in inc	crement	s ot 0.5	V				
		<ul> <li>12v</li> <li>13.75V t</li> </ul>	o 16 75	iV in inc	remento	s of 1V					
		- 15.7501	5 10.13		- en renta	, 01 TA					
		Datum - Him I	£ 1 k -				ما الد				
		Returns the value o output current	i the go	un corre	ection te	ern use	u to cor	rectithe	e measu	liea	
		Format			.inear, tv	vo' <u>s co</u> r	npl <u>eme</u>	ent <u>bina</u>	iry		
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r	r	r	r	r	r	r/w	
38	IOUT_CAL_GAIN	Function	1		Exponer		1		Mantiss	-	YES
		Default Value Bit Position	1 7	0	0	0	1 3	0	0	V 0	
		Access	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	
		Function					tissa	1			
1		Default Value		V: Vo	ariable b	ased o	n factor	v calibr	ation		

Hex Code	Command			Br	ief Desc	cription					Non-Volatile Memory Storage
Couc		Returns the value o	f the of	fset cor	rection	used to	correct	the me	easured	output	
		current Format		1	linear, tv		mnlama	nt hina	n.		
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r	r	r	r	r/w	r	r	
39	IOUT CAL OFFSET	Function			Exponer	nt			Mantiss	a	YES
		Default Value	1	1	1	0	0	V	V	V	-
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r	r/w	r/w	r/w	r/w	r/w	r/w	
		Function					itissa				
		Default Value		V: Vo	ariable k	based o	n factor	y calibr	ration		
		Sets the output ove	rcurren								
		Format			linear, tv	1	-	1	ŕ		
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r	r	r	r	r	r	r	
46	IOUT_OC_FAULT_LIMIT	Function Default Value	1		Exponer		1		Mantiss		YES
		Bit Position	1	1 6	1	1 4	1	0	0	0	
		Access	r	r/w	c/w	r/w	r/w	r/w	r/w	r/w	
		Function		17 VV	17 VV		tissa	17 VV	1/ 1/	1/ 1/	
	Value maybe locked	Default Value	0	1	0	1	1	0	1	0	
	Value maybe locked	Determines module	action	in resn	onse to	an IOLL	ΟΟ ΕΔ		MIT or a	VOLIT	
		undervoltage (UV) f		штезр		un 100 <u>-</u>	_00_1A		in or u	0001	
		Format				Unsigne	d Rinar	<i></i>			
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r	r/w	r/w	r/w	r	r	r	
					RS	RS	RS				
47	IOUT_OC_FAULT_RESPONSE	Function	Х	Х	[2]	[1]	[0]	Х	Х	Х	YES
		Default Value	0	0	1	1	1	1	0	0	
		RS[2:0] – Retry Setti 000 Unit da 111 Unit ga Any other v	pes not pes thro	ugh no	rmal so	ft start o	continuo	ously			
		Sets the output ove IOUT_OC_FAULT_LI			ng level Linear, tu						
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r	r	r	r	r	r	r	
4A	IOUT_OC_WARN_LIMIT	Function	4		Exponer		4		Mantiss		
		Default Value Bit Position	1 7	1 6	5	1 4	1 3	0	0	0	
		Access	/ r	6 r/w	5 r/w	r/w	r/w	2 r/w	1 r/w	0 r/w	
		Function		1 / VV	17 VV		tissa	17 VV	17 VV	17.00	
		Default Value	0	1	0	0	1	0	1	0	
		Sets the overtempe	rature	ault lev	vel in °C						
		Format			inear, t	1			1		
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r	r	r	r	r	r	r	
4F	OT_FAULT_LIMIT	Function	<u>^</u>		Exponer				Mantiss		YES
		Default Value	0	0	0	0	0	0	0	0	
		Bit Position Access	/ r/w	6 r/w	5 r/w	r/w	r/w	2 r/w	1 r/w	0 r/w	
		Function	17 W	17W	1/W		tissa	17 W	1/W	17.00	
	Value may be locked	Default Value	0	1	1	1	1	0	1	0	
	vulue muy be locked			^ontir							

Table 6 (Continued)

Hex Code	Command				Brief	Descript	tion						Non-Volatile Memory Storage
coue		Sets the over tempe	oratur	o warnin		n°C Mi	uct bo lo	wor the					Tremory Storage
		Format	eratur		•			nt binar		AULI_			
		Bit Position	7	6	5	4	Tiplette	2	y 1	0			
		Access	r	r	r	r	r	r	r	r			
		Function			Exponer				1antiss				
51	OT WARN LIMIT	Default Value	0	0	0	0	0	0	0	0			YES
		Bit Position	7	6	5	4	3	2	1	0			
		Access	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w			
		Function			.,		tissa						
		Default Value	0	1	1	0	1	0	0	1			
		Sets the rise time o	f the o	utout vo	Itaae di	irina sta	irtun						
		Supported Values –						Value c	of 0 inst	ructs i	unit to		
		bring its output to p	progra	mmed v	alue as	quickly o	as possi	ble					
		Format						nt binar	У				
		Bit Position	7	6	5	4	3	2	1	0			
61		Access	r	r	r	r	r	r	r	r/w			YES
01	TON_RISE	Function		-	Exponer	1			1antiss	-			TES
		Default Value	1	1	1	0	0	0	0	0			
		Bit Position	7	6	5	4	3	2	1	0			
		Access	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	_		
		Function					tissa		4	1			
		Default Value	0	1	0	0	0	0	1				
		Returns one byte of	infori	mation w					ical mo	dule fo	aults		
		Format	7				d Binary		1				
		Bit Position	7	6	5	4	3	2	1	0 r			
78	STATUS_BYTE	Access	r	r	r	r	r	r	r	None	2		
		Flag	х	OFF	VOUT	IOUT_	VIN_U	TEMP	CML	of the			
		riug	0	OIT	_OV	OC	V	16111	CLIF	Abov	-		
		Default Value	0	0	0	0	0	0	0	0	-		
		Returns two bytes o	of info	rmation	vith a s	ummary	/ of the	module'	's fault/	warni	ng		
		conditions									•		
		Format					Unsigi	ned Bind	ary				
		Bit Position		7	6	5	4	3		2	1		
		Access		r	r	r	r	r		r	r		
		Flag	1	VOUT I	OUT/P	Х	MFR	PGO	DD	х	Х		
79	STATUS WORD				OUT								
		Default Value		0	0	0	0	0		0	0		
		Bit Position		7	6	5	4	3		2	1	$\vdash$	
		Access		r	r	r	r	r	-+	r	r	N.	
		Elaa		хс	FF	VOUT_	IOUT_	0		EMP	CML	No	
		Flag			ΊΓ	OV	C	VIN_		_I*IP	CITL	al	
		Default Value		0	Х	0	0	0		0	0		
		P		-		-	-	-		-	-		
		Returns one byte of	rintori	mation w	ith the s	status o	t the mo	odule's c	output	voltage	e related	1	
		faults Format		_	_	Inciane	d Binary						
7A	STATUS_VOUT	Bit Position		7	6 5		4		2 1	0			
7.4	31A103_V001	Access		r	r i		r		r r	r	_		
		Flag	VOI	JT_OV	XX		JT_UV		X X	X	-		
		Default Value		0	0 0		0		0 0	0	1		
		-											
		Returns one byte of information with the status of the module's output current related											
		faults										<b>-</b>	
70		Format Bit Position		7	6	Unsi	gned Bi	nary	/1 7	2 2			
7B	STATUS_IOUT	Access		/ r	r		5 r		4 3 r r		1 0 r r	-	
		Flag	1011	T_OC Fai			OC War	mina	XX		XX	_	
		Default Value	100	0		1001	00 000	····y	0 0		0 0	_	
				~		I	~		<u> </u>				

Hex Code	Command					Brief De	escripti	on							ſ	Non-Volatile Memory Storage
		Returns one byte	of infor	matic	on witl	h the sto	atus of	the r	modul	e's t	empe	ratur	e rel	ated		
		faults						0.								
7D		Format Bit Position		7		0r 6	nsigned 5			3	2	1	0			
70	STATUS_TEMPERATURE	Access		r		r	r		r i		r	r	r			
		Flag	OT	FAUL	.T (	DT_WAR					Х	Х	X			
		Default Value		0		0	0		0 (	)	0	0	0			
		Returns one byte faults	of infor	matic	on witl					e's c	omm	unico	ation	related	b	
		Format	-		6		Jnsigne	ed Bi		2	-	1		0		
7E	STATUS CMI	Bit Position Access	7 r		6 r	5 r	4 r		3 r	2 r	-	1 r		0 r		
/ ⊑	STATUS_CML	Flag	Invc Comn	ılid	Inval	id PEC	Memo faul	ť	X	X		)ther omm		X		
							detect	ted			F	ault				
		Default Value	0		0	0	0		0	0		0		0		
		Returns one byte of information with the status of the module specific faults or warning Format Unsigned Binary												g		
		Format	_		-		1									
		Bit Position	7	6	5	4	3	2	1		0					
		Access	r	r	r	r	r	r	r		R					
80	STATUS_MFR_SPECIFIC	Flag	OTFI	×	Х	IVADDI		Х	Х	ΤW	OPH_	EN				
		Default Value OTFI – Internal Ter IVADDR – PMBUs ( TWOPH_EN – Moo	addres	s is no	ot vali	d	0 Shutdo	0 own	0 thresl	nold	0					
		Returns the value	ofthe	outou	it volt	nne of th		مارر	Evno	nont	ic five	h ha	-9			
		Format		Juipe		iear, two							-9.			
		Bit Position	7		6	5	4	3	-	2	1		0			
		Access	r		r	r	r	r		r	r		r			
8B	READ_VOUT	Function Default Value	0		0	0	Manti 0	ssa 0		)	0	-	0			
		Bit Position	7		6	5	4	3		2	1		0			
		Access	r		r	r	r	r		r	r	_	r			
		Function					Manti									
		Default Value	0		0	0	0	0	(	)	0		0			
		Returns the value	of the	outpu	it curr	ent of th	ne mod	ule							+	
		Format				iear, two			nent b	inar	У					
		Bit Position	7		6	5	4	3		2	1		0			
		Access	r		r	r	r	R		r N	r		r			
8C	READ_IOUT	Function Default Value	1		1 EX	ponent 1	0	0	\	۳ /	1antis V		V			
00	1001	Bit Position	7		6	5	4	3		2	1		0			
		Access	r		r	r	r	r		r	r		r			
		Function					Manti									
		Default Value	V		V	V	V	V	١	/	V		0			
		V - Variable														

#### Table 6 (Continued)

Hex Code	Command		Brief Description										
couc		Returns the value a	f the ex	ternal t	tempera	ture in o	dearee	Celsius				Memory Storage	
		Format			_inear, tv				rv				
		Bit Position	7	6	5	4	3	2	1	0			
		Access	r	r	r	r	R	r	r	r			
		Function			Exponer				Mantiss				
8E	READ TEMPERATURE 2	Default Value	0	0	0	0	0	V	V	V			
OL	READ_TEMPERATORE_2	Bit Position	7	6	5	4	3	2	1	0			
		Access	r	r	r	r	r	r	r	r			
			1										
		Function Default Value	V	V	V	Mun V	tissa V	V	V	0			
		V - Variable	V	V	V	V	V	V	V	0			
		v - variable											
		Returns one byte in	dicatin	a tha m	indula is	compli	ant to P	MRus S	nec 11	(read o	oly)		
		Format	uicutin	g the m			d Binar		pec. 1.1	lieuu o	iiy)		
98		Bit Position	7	6	5	4	3	2	1	0			
90	PMBUS_REVISION	Access		r	r	r r		r					
		Default Value	r O	0	0	1	r	0	r	r 1			
		Default value	0	0	0	1	0	0	0	1	_		
		Returns module na	mo info	rmatio	2								
		Format		mutio		Inciana	d Dinar				l i		
		Bit Position	7	6		unsigne 4	d Binar	·	1	0			
				6	5		3	2	1	0			
		Access	r	r	r	r	r	r	r	r			
DO	MFR SPECIFIC 00	Function					erved					YES	
-		Default Value	0	0	0	0	0	0	0	0			
		Bit Position	7	6	5	4	3	2	1	0			
		Access	r	r	r	r	r	r	r	r			
		Function			1	e Name				erved			
		Default Value	0	1	0	0	1	1	0	0			
		Applies a fixed offse steps. Permissible v as VREF_TRIMx2 <sup>-9</sup> . I Format	alues ro	ange be nt fixed	etween - at -9(de	120mV c)	and +6	0mV. Th	ne offset				
		Bit Position	7	1	_inear, tv 5	4 vo s coi		2	1	0			
		Access	r/w	6		4	3		1	0			
D4	VREF TRIM	Function	T/W	r	r	Man	tiona	r	r	r		YES	
	_						tissa	11					
		Default Value	V 7	V	V	V	V	V	V	V 0			
		Bit Position	· ·	6	5	4	3	2	1	-			
		Access	r	r	r/w	r/w	r/w	r/w	r/w	r/w			
		Function					tissa						
		Default Value	V	V	V	V	V	V	V	V			
		Applies a fixed offse Permissible values (STEP_VREF_MARGI voltage includes VR Format Bit Position	range b N_HIGH	etweer H + VRE M adjus	n 0mV ar F_TRIM);	nd +60n ≺2⁻º. Exp nd rang	nV. The bonent f jes from	offset is fixed at n -30% f	s calculo -9(dec). to 10%	ated as			
D5	STEP_VREF_MARGIN_HIGH	Access	r	r	r	r	r	r	r	r		YES	
		Function				Man	tissa						
		Default Value	V	V	V	V	V	V	V	V			
		Bit Position	7	6	5	4	3	2	1	0			
		Access	r	r	r	r/w	r/w	r/w	r/w	r/w			
		Function		. ·	. ·		tissa						
		Default Value	V	V	V	V	V	V	V	V			
			v	v	, v	v	v	v	v	v			

#### Table 6 (Continued)

Function         Mantissa           Default Value         V<	Hex Code	Command				Brie	ef De	escripti	ion					Non-Volatile Memory Storage
D6         STEP_VREF_MARGIN_LOW         Bit Position         7         6         5         4         3         2         1         0           D6         STEP_VREF_MARGIN_LOW         Access         r			steps. Permissible values range between -120mV and 0mV) The offset is calculated as (STEP_VREF_MARGIN_LOW + VREF_TRIM)x2 <sup>.9</sup> .Exponent fixed at -9(dec). Net output voltage includes VREF_TRIM adjustment and ranges from -30% to 10%											
D6         STEP_VREF_MARGIN_LOW         Access         r </td <td></td> <td></td> <td>Format</td> <td></td> <td></td> <td>Linec</td> <td>ır, tv</td> <td>vo's cor</td> <td>npleme</td> <td>nt bina</td> <td>ry</td> <td></td> <td></td> <td></td>			Format			Linec	ır, tv	vo's cor	npleme	nt bina	ry			
Disc         Function         Function         Montissa           Default Value         V			Bit Position	7	6	5		4	3	2	1	0		
Default Value         V         <	D6	STEP VREF MARGIN LOW	Access	r	r	r		r	r	r	r	r		YES
Bit Position         7         6         5         4         3         2         1         0           Access         r         r         r         r/w         r/w <thr th="" w<=""> <th< td=""><td></td><td></td><td>Function</td><td></td><td></td><td></td><td></td><td>Man</td><td>tissa</td><td></td><td></td><td></td><td></td><td></td></th<></thr>			Function					Man	tissa					
Access         r         r         r/w			Default Value	V	V	V	'	V	V	V	V	V		
Function         Mantissa           Default Value         V<			Bit Position	7	6	5		4	3	2	1	0		
Default Value         V         <			Access	r	r	r/v	N	r/w	r/w	r/w	r/w	r/w		
D7         PCT_VOUT_FAULT_PG_LIMIT         Format         Unsigned Binary           D7         PCT_VOUT_FAULT_PG_LIMIT         Format         Unsigned Binary           Bit Position         7         6         5         4         3         2         1         0           Access         r <td></td> <td></td> <td></td> <td></td> <td></td> <td></td> <td></td> <td>Man</td> <td>tissa</td> <td></td> <td></td> <td></td> <td></td> <td></td>								Man	tissa					
D7         PCT_VOUT_FAULT_PG_LIMIT         Format         Unsigned Binary           Bit Position         7         6         5         4         3         2         1         0           Access         r				•	•			•	•			V		
Bit Position         7         6         5         4         3         2         1         0           Access         r			VOUT_OVER_VOLTA					age of I	nomina					
D7         PCT_VOUT_FAULT_PG_LIMIT         Access         r			Format			<u> </u>		Uns	signed I	Binary				
D7         PCT_VOUT_FAULT_PG_LIMIT         Function         X <t< td=""><td></td><td></td><td>Bit Position</td><td>7</td><td></td><td>6</td><td>5</td><td></td><td>4</td><td>3</td><td>2</td><td>1</td><td>0</td><td></td></t<>			Bit Position	7		6	5		4	3	2	1	0	
D7       PCT_VOUT_FAULT_PG_LIMIT       Performation       X <thx< th=""> <thx< th="">       X</thx<></thx<>			Access	r		r	r		r	r	r	r/w	r/w	
D7       PCI_VOOT_INDEL_FO_LIMIT       PAGE Command Truth Table         PAGE Command Truth Table       PCT_LS       UV (%)       PGL       PGH       PGH       LOW       OV (%)         SB       B       UV (%)       PGL       HIGH       HIGH       LOW       (%)       (%)       (%)         0       0       -16.67       -12.5       -8.33       12.5       8.33       16.67         0       1       -12.5       -8.33       -4.17       8.33       4.17       12.5         1       0       -29.17       -20.83       -16.67       8.33       4.17       12.5         1       1       -41.67       -37.5       -33.33       8.33       4.17       12.5         1       1       -41.67       -37.5       -33.33       8.33       4.17       12.5         1       1       -41.67       -37.5       -33.33       8.33       4.17       12.5         Used to set delay to turn-on or turn-off modules as a ratio of TON_RISE. Values can range from 0 to 7 and are a multiple of TON_RISE TIME       Format       Unsigned Binary         D8       SEQUENCE_TON_TOFF_DELAY       Bit Position       7       6       5       4       3       2       1			Function	×		х	х		×	х	х			
D7       PCI_VOOT_I AULT_FO_LIMIT       PAGE Command Truth Table         PAGE Command Truth Table       PCT_LS       UV (%)       PGL       PGH       PGH       LOW       (%)         SB       B       UV (%)       PGL       PGL       PGH       HIGH       LOW       (%)       (%)       (%)         0       0       -16.67       -12.5       -8.33       12.5       8.33       16.67         0       1       -12.5       -8.33       -4.17       8.33       4.17       12.5         1       0       -29.17       -20.83       -16.67       8.33       4.17       12.5         1       1       -41.67       -37.5       -33.33       8.33       4.17       12.5         1       1       -41.67       -37.5       -33.33       8.33       4.17       12.5         Used to set delay to turn-on or turn-off modules as a ratio of TON_RISE. Values can range from 0 to 7 and are a multiple of TON_RISE TIME       Format       Unsigned Binary         D8       SEQUENCE_TON_TOFF_DELAY       Bit Position       7       6       5       4       3       2       1       0         Access       r/w       r/w       r/w       r/w       r/w	07		Default Value	0		х	X		x	X	X	0	0	
PCT_M SB         PCT_LS B         UV (%) B         PGL LOW (%)         PGH HIGH (%)         PGH LOW (%)         PGH LOW (%)         OV (%) C           0         0         -16.67         -12.5         -8.33         12.5         8.33         16.67           0         1         -12.5         -8.33         -4.17         8.33         4.17         12.5           1         0         -29.17         -20.83         -16.67         8.33         4.17         12.5           1         1         -41.67         -37.5         -33.33         8.33         4.17         12.5           1         1         -41.67         -37.5         -33.33         8.33         4.17         12.5           1         0         -29.17         -20.83         -16.67         8.33         4.17         12.5           1         1         -41.67         -37.5         -33.33         8.33         4.17         12.5           Used to set delay to turn-on or turn-off modules as a ratio of TON_RISE. Values can range from 0 to 7 and are a multiple of TON_RISE TIME         Used to set delay to turn-on or turn-off modules as a ratio of TON_RISE. Values can range from 0 to 7 and are a multiple of TON_RISE TIME           Bit Position         7         6         5         4	07	PCI_VOUI_FAULI_PG_LIMII		-		~	~		~	~	~	0	Ū	
0         1         -12.5         -8.33         -4.17         8.33         4.17         12.5           1         0         -29.17         -20.83         -16.67         8.33         4.17         12.5           1         1         1         -41.67         -37.5         -33.33         8.33         4.17         12.5           1         1         1         -41.67         -37.5         -33.33         8.33         4.17         12.5           1         1         1         -41.67         -37.5         -33.33         8.33         4.17         12.5           1         1         1         -41.67         -37.5         -33.33         8.33         4.17         12.5           Used to set delay to turn-on or turn-off modules as a ratio of TON_RISE. Values can range from 0 to 7 and are a multiple of TON_RISE TIME         Image: Format Unsigned Binary         Image: Format Unsi			PCT_M PCT_LS	UV	(%)	LOV (%	V )	HIGI (%)	H H	IGH (%)	LOW (%)		/ (%)	
I         0         -29.17         -20.83         -16.67         8.33         4.17         12.5           1         1         -41.67         -37.5         -33.33         8.33         4.17         12.5           1         1         -41.67         -37.5         -33.33         8.33         4.17         12.5           Used to set delay to turn-on or turn-off modules as a ratio of TON_RISE. Values can range from 0 to 7 and are a multiple of TON_RISE TIME         Image: Comparison of the table of the table of table			0 0	-16	.67	-12.	5	-8.3	3 1	2.5	8.33	16	5.67	
I         I         -41.67         -37.5         -33.33         8.33         4.17         12.5           Image: Description of the second seco			0 1	-12	2.5	-8.3	3	-4.1	7 8	3.33	4.17	1	2.5	
D8     SEQUENCE_TON_TOFF_DELAY     Bit Position     7     6     5     4     3     2     1     0       Access     r/w     r/w <t< td=""><td></td><td></td><td>1 0</td><td>-29</td><td>.17</td><td>-20.8</td><td>33</td><td>-16.6</td><td>57 8</td><td>3.33</td><td>4.17</td><td>1</td><td>2.5</td><td></td></t<>			1 0	-29	.17	-20.8	33	-16.6	57 8	3.33	4.17	1	2.5	
from 0 to 7 and are a multiple of TON_RISE TIME           Format         Unsigned Binary           Bit Position         7         6         5         4         3         2         1         0           Access         r/w         r/w <td></td>														
D8         SEQUENCE_TON_TOFF_DELAY         Bit Position         7         6         5         4         3         2         1         0           Access         r/w         r/w         r/w         r/w         r         r/w			from 0 to 7 and are				ISE <sup>-</sup>	TIME			RISE. V	alues co	an range	
Access r/w r/w r r/w r/w r/w r	00			7	6	5			1		1 1	0		
	00	SLQULINCE_ION_IOFF_DELAY			-				-				-	
			Function					i.				+ '	-	
Default Value         0         <							)	0				0	1	

#### **Digital Power Insight (DPI)**

GE offers a software tool that set helps users evaluate and simulate the PMBus performance of the UJT035 modules without the need to write software.

The software can be downloaded for free at <a href="http://go.ge-energy.com/DigitalPowerInsight.html">http://go.ge-energy.com/DigitalPowerInsight.html</a>. A GE USB to I2C adapter and associated cable set are required for proper functioning of the software suite. For first time users, the GE DPI Evaluation Kit can be purchased from leading distributors at a nominal price and can be used across the entire range of GE Digital POL Module.

## **Thermal Considerations**

GE

Power modules operate in a variety of thermal environments; however, sufficient cooling should always be provided to help ensure reliable operation.

Considerations include ambient temperature, airflow, module power dissipation, and the need for increased reliability. A reduction in the operating temperature of the module will result in an increase in reliability. The thermal data presented here is based on physical measurements taken in a wind tunnel. The test set-up is shown in Figure 42. The preferred airflow direction for the module is in Figure 43.

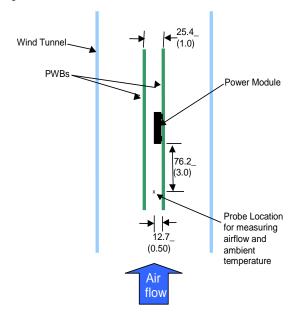


Figure 42. Thermal Test Setup.

The thermal reference point,  $T_{ref}$  used in the specifications is shown in Figure 43. For reliable operation, the temperature at this points should not exceed 115°C. The output power of the module should not exceed the rated power of the module (Vo,set x Io,max).

Please refer to the Application Note "Thermal Characterization Process For Open-Frame Board-Mounted Power Modules" for a detailed discussion of thermal aspects including maximum device temperatures.

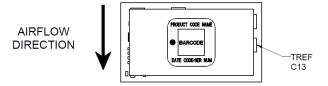


Figure 43. Preferred airflow direction and location of hotspot of the module (Tref).

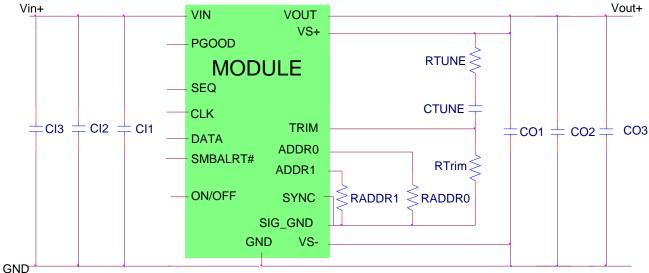
# 35A Digital MicroDLynxII™: Non-Isolated DC-DC Power Modules

4.5Vdc -14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

## **Example Application Circuit**

## **Requirements:**

Vin:	12V
Vout:	1.8V
lout:	26A max., worst case load transient is from 17.5A to 26A
∆Vout:	1.5% of Vout (27mV) for worst case load transient
Vin, ripple	1.5% of Vin (180mV, p-p)



CI1

Decoupling caps - 1x0.047µF/16V 0402 or 0306ceramic capacitor (e.g. Murata LLL185R71C473MA01) +
1x0.1uF/16V 0402 ceramic cpacitor

- CI2 6x22µF/16V ceramic capacitor (e.g. Murata GRM32ER61C226KE20)
- CI3 47µF/16V bulk electrolytic
- Decoupling cap 1x0.047µF/16V ceramic capacitor (e.g. Murata LLL185R71C473MA01) + 1x0.1uF/16V 0402 CO1 ceramic cpacitor
- CO2 8 x 47uF/6.3V 1210 ceramic capacitor
- CO3 4 x 330uF/6V POSCAP
- 3300pF ceramic capacitor (can be 1206, 0805 or 0603 size) CTune
- RTune  $300\Omega$  SMT resistor (can be 1206, 0805 or 0603 size)
- RTrim  $10k\Omega$  SMT resistor (can be 1206, 0805 or 0603 size, recommended tolerance of 0.1%)

#### Note: The DATA, CLK and SMBALRT pins do not have any pull-up resistors inside the module. Typically, the SMBus master controller will have the pull-up resistors as well as provide the driving source for these signals.

# 35A Digital MicroDLynxII<sup>™</sup>: Non-Isolated DC-DC Power Modules

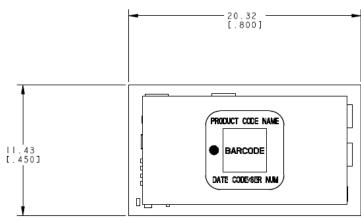
4.5Vdc -14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

#### **Mechanical Outline**

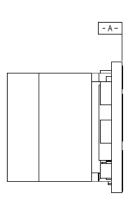
Dimensions are in millimeters and (inches).

Tolerances: x.x mm  $\pm$  0.5 mm (x.xx in.  $\pm$  0.02 in.) [unless otherwise indicated]

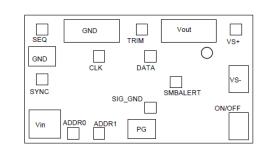
x.xx mm  $\pm$  0.25 mm (x.xxx in  $\pm$  0.010 in.)



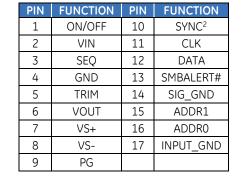
TOP VIEW



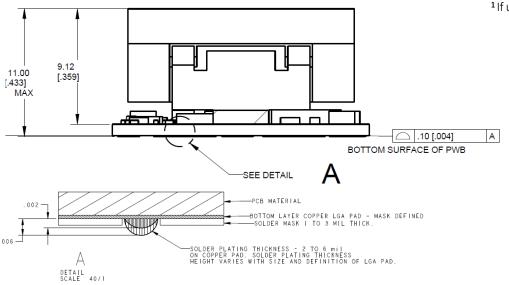
SIDE VIEW



BOTTOM VIEW



<sup>1</sup> If unused, connect to SIG\_GND



# 35A Digital MicroDLynxII<sup>TM</sup>: Non-Isolated DC-DC Power Modules

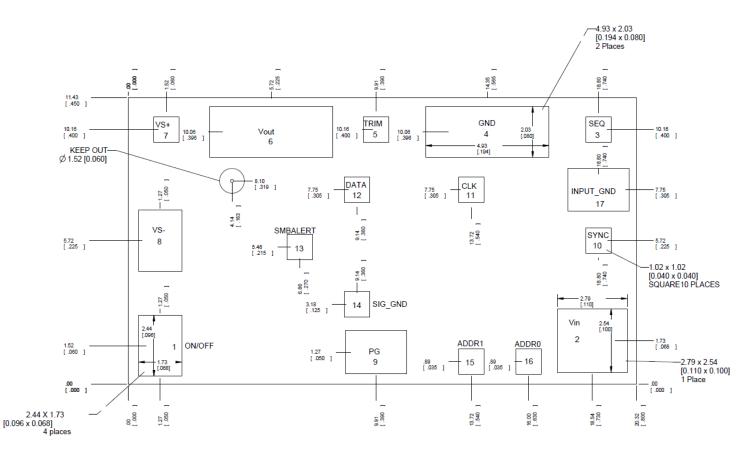
4.5Vdc -14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

## **Recommended Pad Layout**

Dimensions are in millimeters and (inches).

Tolerances: x.x mm  $\pm$  0.5 mm (x.xx in.  $\pm$  0.02 in.) [unless otherwise indicated]

x.xx mm  $\pm$  0.25 mm (x.xxx in  $\pm$  0.010 in.)



PIN	FUNCTION	PIN	FUNCTION
1	ON/OFF	10	SYNC <sup>2</sup>
2	VIN	11	CLK
3	SEQ	12	DATA
4	GND	13	SMBALERT#
5	TRIM	14	SIG_GND
6	VOUT	15	ADDR1
7	VS+	16	ADDR0
8	VS-	17	INPUT_GND
9	PG		

<sup>2</sup> If unused, connect to SIG\_GND.

GE

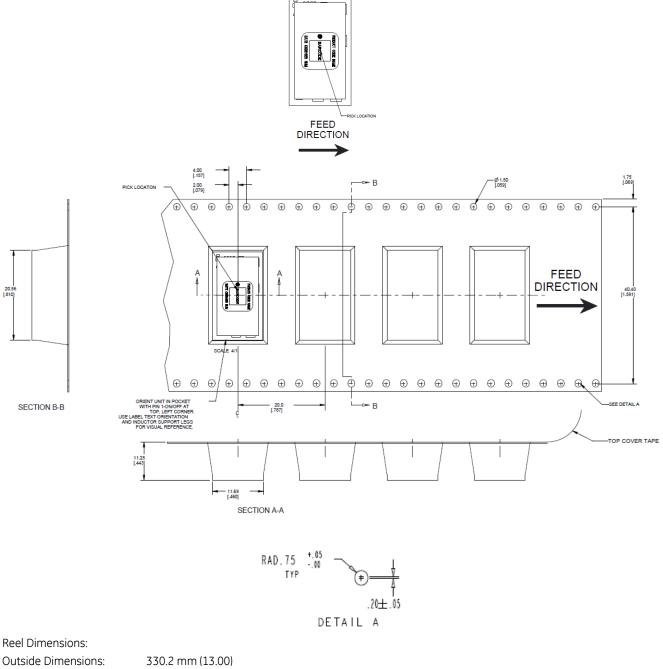
# 35A Digital MicroDLynxII<sup>TM</sup>: Non-Isolated DC-DC Power Modules

4.5Vdc -14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

## **Packaging Details**

The 12V Digital MicroDLynxII<sup>™</sup> 35A modules are supplied in tape & reel as standard. Modules are shipped in quantities of 200 modules per reel.

All Dimensions are in millimeters and (in inches).



Outside Dimensions:	330.2 mm (13.00)
Inside Dimensions:	177.8 mm (7.00")
Tape Width:	44.00 mm (1.732")

## 35A Digital MicroDLynxII<sup>TM</sup>: Non-Isolated DC-DC Power Modules 4.5Vdc -14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

## **Surface Mount Information**

#### Pick and Place

The 35A Digital MicroDLynxII<sup>™</sup> modules use an open frame construction and are designed for a fully automated assembly process. The modules are fitted with a label designed to provide a large surface area for pick and place operations. The label meets all the requirements for surface mount processing, as well as safety standards, and is able to withstand reflow temperatures of up to 300°C. The label also carries product information such as product code, serial number and the location of manufacture.

#### **Nozzle Recommendations**

The module weight has been kept to a minimum by using open frame construction. Variables such as nozzle size, tip style, vacuum pressure and placement speed should be considered to optimize this process. The minimum recommended inside nozzle diameter for reliable operation is 3mm. The maximum nozzle outer diameter, which will safely fit within the allowable component spacing, is 7 mm.

#### **Bottom Side / First Side Assembly**

This module is not recommended for assembly on the bottom side of a customer board. If such an assembly is attempted, components may fall off the module during the second reflow process.

#### Lead Free Soldering

The modules are lead-free (Pb-free) and RoHS compliant and fully compatible in a Pb-free soldering process. Failure to observe the instructions below may result in the failure of or cause damage to the modules and can adversely affect long-term reliability.

#### **Pb-free Reflow Profile**

Power Systems will comply with J-STD-020 Rev. C (Moisture/Reflow Sensitivity Classification for Nonhermetic Solid State Surface Mount Devices) for both Pb-free solder profiles and MSL classification procedures. This standard provides a recommended forced-air-convection reflow profile based on the volume and thickness of the package (table 4-2). The suggested Pb-free solder paste is Sn/Ag/Cu (SAC). For questions regarding Land grid array(LGA) soldering, solder volume; please contact GE for special manufacturing process instructions. The recommended linear reflow profile using Sn/Ag/Cu solder is shown in Fig. 44. Soldering outside of the recommended profile requires testing to verify results and performance.

#### **MSL Rating**

The 35A Digital MicroDLynxII^m modules have a MSL rating of 2A.

#### **Storage and Handling**

The recommended storage environment and handling procedures for moisture-sensitive surface mount packages is detailed in J-STD-033 Rev. A (Handling, Packing, Shipping and Use of Moisture/Reflow Sensitive Surface Mount Devices). Moisture barrier bags (MBB) with desiccant are required for MSL ratings of 2 or greater. These sealed packages should not be broken until time of use. Once the original package is broken, the floor life of the product at conditions of  $\leq$  30°C and 60% relative humidity varies according to the MSL rating (see J-STD-033A). The shelf life for dry packed SMT packages will be a minimum of 12 months from the bag seal date, when stored at the following conditions:  $< 40^{\circ}$  C, < 90% relative humidity.

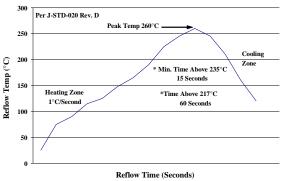


Figure 44. Recommended linear reflow profile using Sn/Ag/Cu solder.

#### Post Solder Cleaning and Drying Considerations

Post solder cleaning is usually the final circuit-board assembly process prior to electrical board testing. The result of inadequate cleaning and drying can affect both the reliability of a power module and the testability of the finished circuit-board assembly. For guidance on appropriate soldering, cleaning and drying procedures, refer to *Board Mounted Power Modules: Soldering and Cleaning* Application Note (AN04-001).

# 35A Digital MicroDLynxII<sup>™</sup>: Non-Isolated DC-DC Power Modules

4.5Vdc -14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

## **Ordering Information**

Please contact your GE Sales Representative for pricing, availability and optional features.

#### **Table 9. Device Codes**

Device Code	Input Voltage Range	Output Voltage	Output Current	On/Off Logic	Sequencing	Comcodes
UJT035A0X3-SRZ	4.5 – 14.4Vdc	0.51 – 3.63Vdc	35A	Negative	Yes	150047126
UJT035A0X43-SRZ	4.5 – 14.4Vdc	0.51 – 3.63Vdc	35A	Positive	Yes	150047127

-Z refers to RoHS compliant parts

#### Table 10. Coding Scheme

Package Identifier	Family	Sequencing Option	Output current	Output voltage	On/Off logic	Remote Sense	Options		ROHS Compliance
U	J	Т	035A0	×		3	-SR		Z
P=Pico U=Micro M=Mega G=Giga	J=DLynx II Digital K = DLynxII Analog.	T=with EZ Sequence X=without sequencing	35A	X = programm able output	4 = positive No entry = negative	3 = Remote Sense	S = Surface Mount R = Tape & Reel	No entry = Standard D = 105°C operating ambient, 40G operating shock as per MIL Std 810F	Z = ROHS6

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See Digital Non-Isolated Decipional Us2004173882A1, US2005200344, US20050203240, US200409240734, US200409240734, US2004093533A1, US20041931241, US200617516A1, US20061751451, US200517516A1, US20061751451, US2005175174, US2006175144, U W004062061 A1, W004062062A1, W004070780A3, W004084390A3, W004084391A3, W005079227A3, W005081771A3, W006019569A3, W02007001584A3, W02007094935A3

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